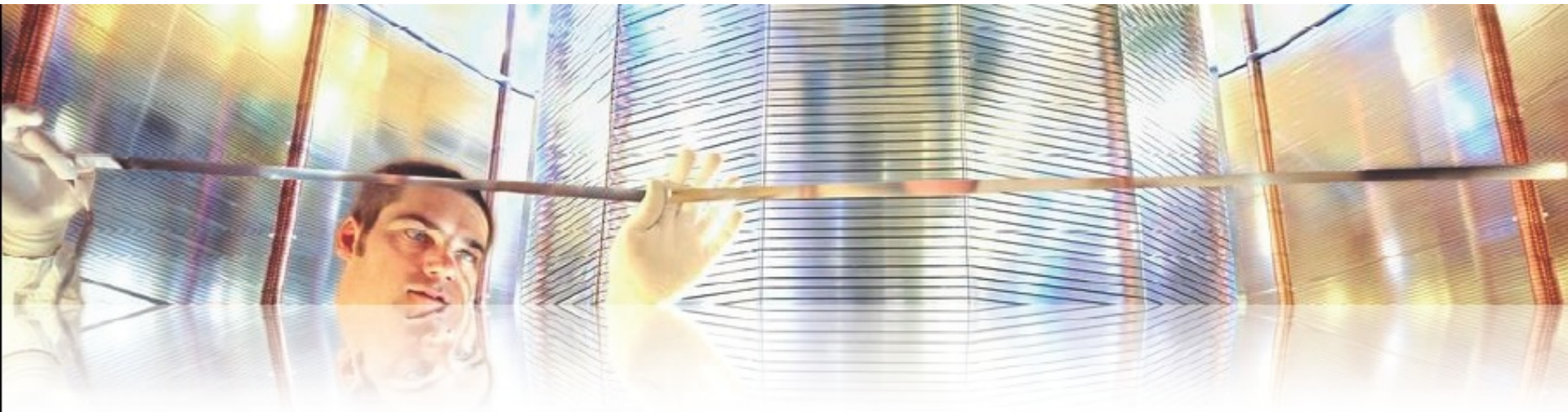


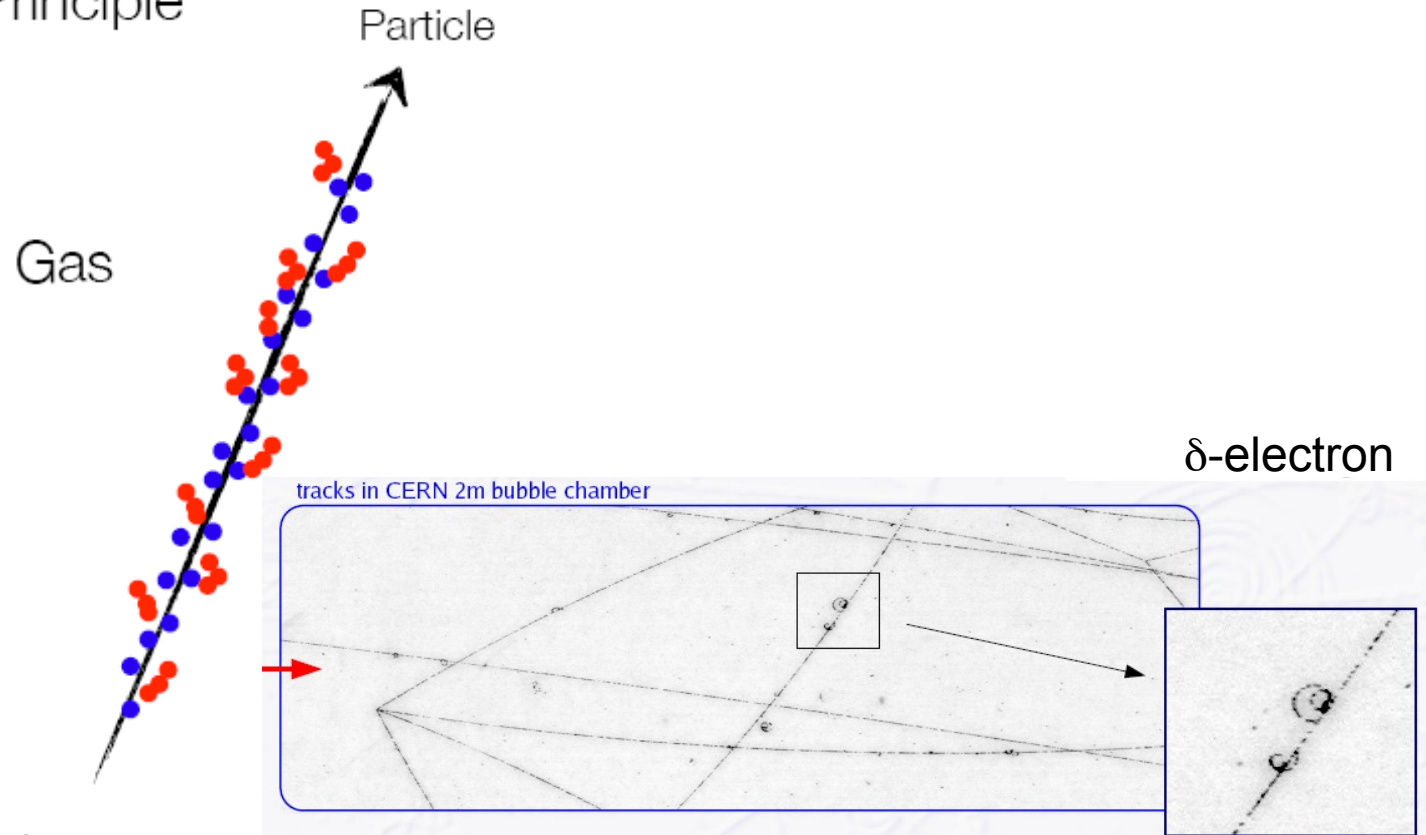
Gaseous detectors

measurement of ionization
position determination



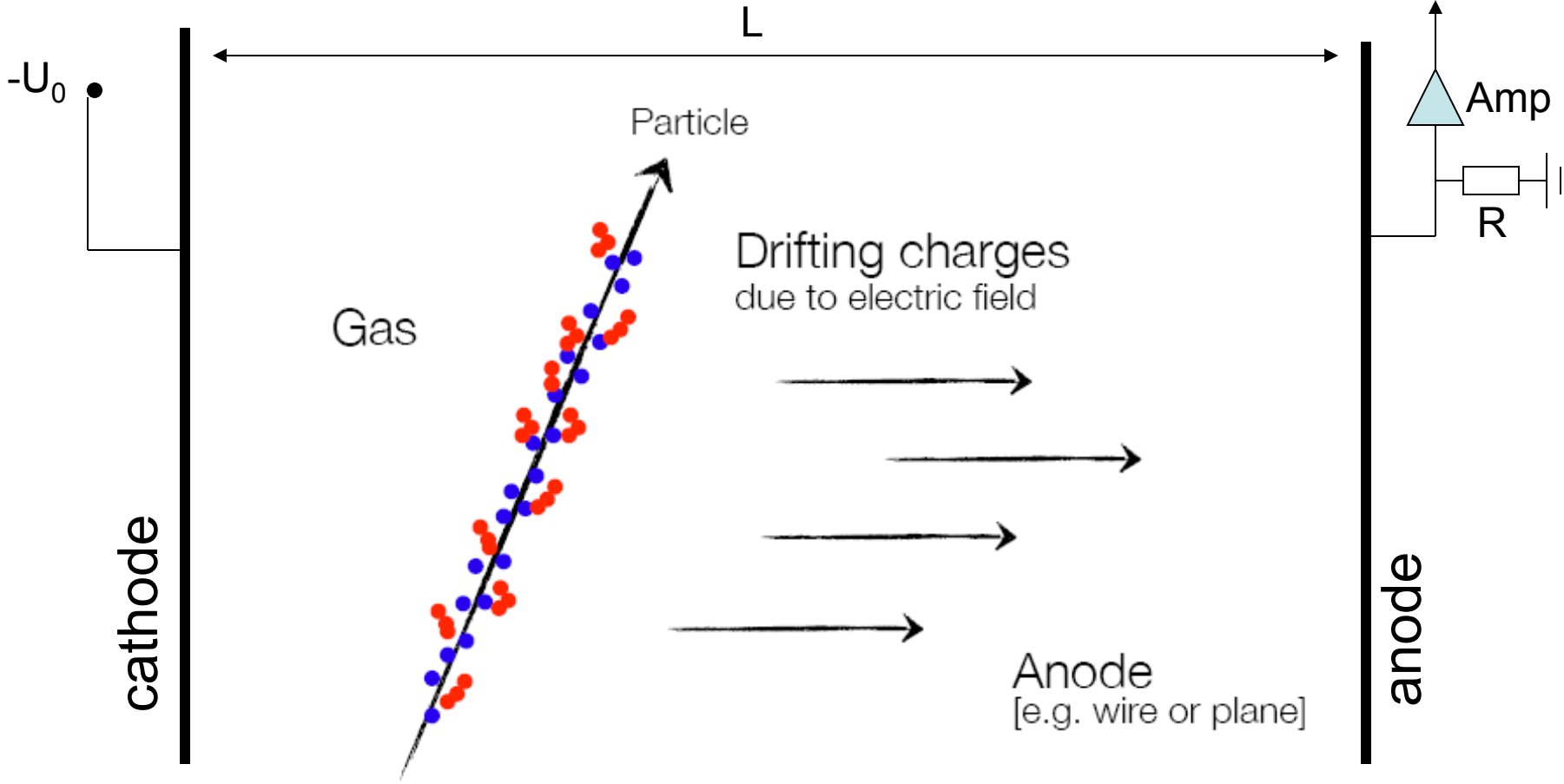
Introduction

Schematic Principle of gas detectors



- Primary Ionization
- Secondary Ionization (due to δ -electrons)

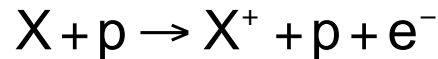
Introduction



- Primary Ionization
- Secondary Ionization (due to δ -electrons)

Ionization

Primary ionization



p = charge particle traversing the gas
 X = gas atom
 e^- = delta-electron (δ)

Secondary ionization



if E_δ is high enough ($E_\delta > E_i$)

Relevant Parameters for gas detectors

Ionization energy	:	E_i
Average energy/ion pair	:	W_i
Average number of primary ion pairs [per cm]	:	n_p
Average number of ion pairs [per cm]	:	n_T

Differences
due to δ -electrons

$$\langle n_T \rangle = \frac{L \cdot \langle \frac{dE}{dx} \rangle_i}{W_i}$$

[about 2-6 times n_p]
 [L: layer thickness]

Typical values:

$E_i \sim 30 \text{ eV}$
 $n_T \sim 100 \text{ pairs / 3 keV incident particle}$

Table for most common gases

($E_i = I_0$)

Gas	ρ (g/cm ³) (STP)	I_0 (eV)	W_i (eV)	dE/dx (MeVg ⁻¹ cm ²)	n_p (cm ⁻¹)	n_t (cm ⁻¹)
H ₂	$8.38 \cdot 10^{-5}$	15.4	37	4.03	5.2	9.2
He	$1.66 \cdot 10^{-4}$	24.6	41	1.94	5.9	7.8
N ₂	$1.17 \cdot 10^{-3}$	15.5	35	1.68	(10)	56
Ne	$8.39 \cdot 10^{-4}$	21.6	36	1.68	12	39
Ar	$1.66 \cdot 10^{-3}$	15.8	26	1.47	29.4	94
Kr	$3.49 \cdot 10^{-3}$	14.0	24	1.32	(22)	192
Xe	$5.49 \cdot 10^{-3}$	12.1	22	1.23	44	307
CO ₂	$1.86 \cdot 10^{-3}$	13.7	33	1.62	(34)	91
CH ₄	$6.70 \cdot 10^{-4}$	13.1	28	2.21	16	53
C ₄ H ₁₀	$2.42 \cdot 10^{-3}$	10.8	23	1.86	(46)	195

Quelle: K. Kleinknecht, *Detektoren für Teilchenstrahlung*, B.G. Teubner, 1992

Ionization statistics

Production of ion/electron pairs is a Poissonian distributed

$$P(n_p, \langle n_p \rangle) = \frac{\langle n_p \rangle^{n_p} e^{-\langle n_p \rangle}}{n_p!}$$

with $\langle n_p \rangle = L/\lambda$ and $\lambda = 1/(n_e \sigma_I)$

σ_I : Ionization x-Section
 n_e : Electron density
 L : Thickness

Recombination and electron attachment:

Admixture of electronegative gases (O_2 , F, Cl) influences detection efficiency

Diffusion:

Influences the spatial resolution ...

Mobility of charges:

Influences the timing behavior of gas detectors ...

Avalanche process via impact ionization:

Important for the gain factor of the gas detector ...

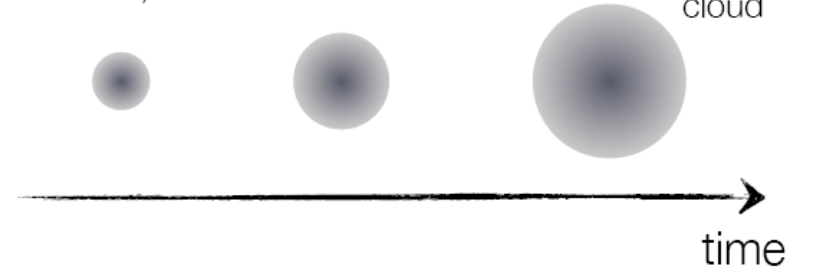
Transport of electrons/ions in gas

Diffusion:

classical kinetic theory of gases

$$\frac{dN}{dx} = \frac{N_0}{\sqrt{4\pi Dt}} \exp\left(-\frac{x^2}{4Dt}\right)$$

Diffusion
without E,B field



after a diffusion time t the electrons/ions are Gaussian distributed with a spread

$$\sigma(r) = \sqrt{6Dt} \quad \text{where } D \text{ is the diffusion coefficient}$$

$$D = \frac{1}{3} v \lambda$$

the mean free path of electrons/ions in the gas:

$$\lambda = \frac{1}{\sqrt{2}} \frac{kT}{\sigma_0 P}$$

the mean velocity according to Maxwell distribution:

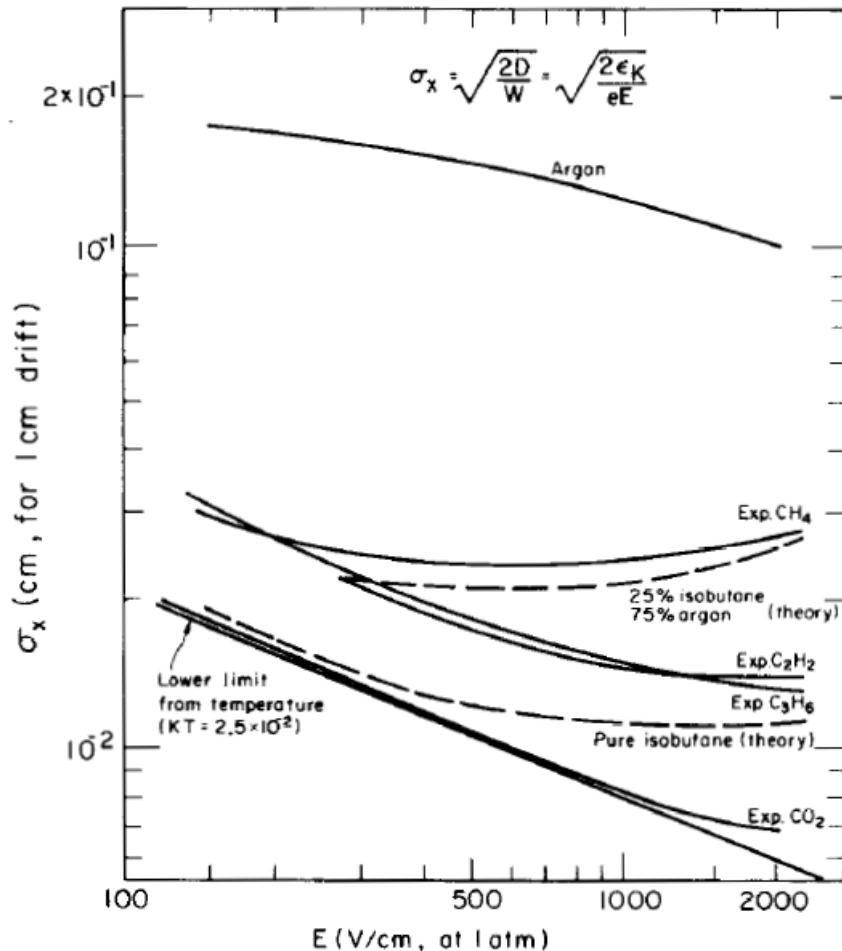
$$v = \sqrt{\frac{8kT}{\pi m}}$$

m =mass of particle

$$D = \frac{1}{3} v \lambda = \frac{2}{3\sqrt{\pi}} \frac{1}{P\sigma_0} \sqrt{\frac{(kT)^3}{m}}$$

D depends on gas pressure P and temperature T

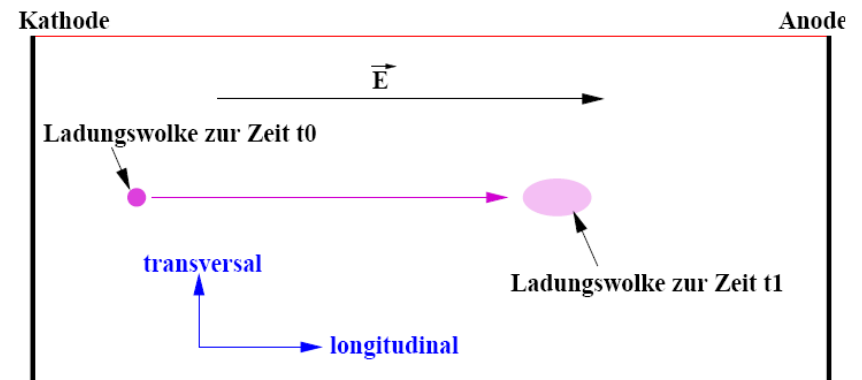
Diffusion in electric field



Drift in direction of E-field superimposed to statistical diffusion

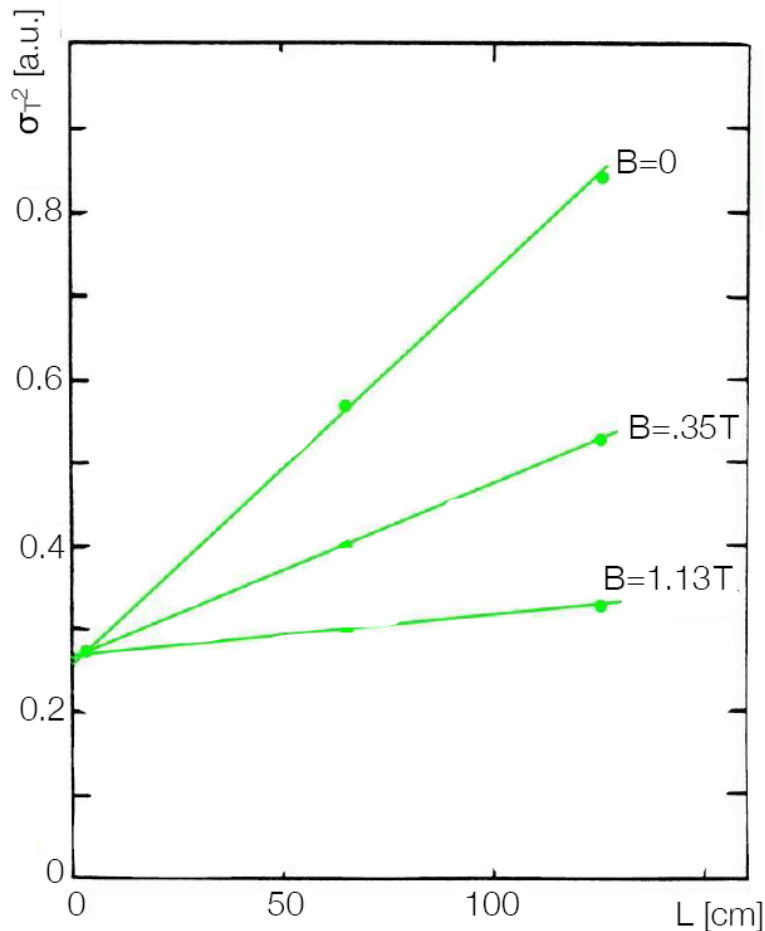
Extra velocity influences longitudinal diffusion

Transverse diffusion not affected



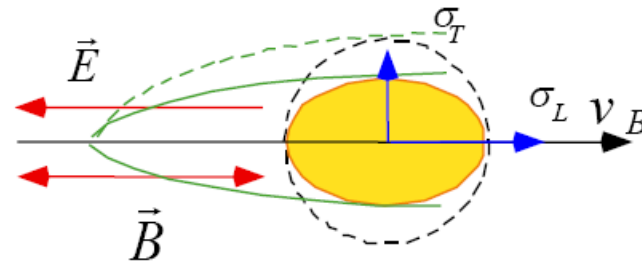
E-field reduced diffusion in longitudinal direction

Diffusion in magnetic field



In the presence of a B-field different effects on longitudinal and transverse diffusion

No Lorentz force along B-field direction



Transverse diffusion as function of drift length for different B fields

B-Field can substantially reduce diffusion in transverse direction

Transport of electrons/ions in gas

Drift and Mobility:

with external E-field: electrons/ions obtain velocity v_D in addition to thermal motion; on average electrons/ions move along field lines of electric field E

$$\vec{v}_D = \mu_{\pm} |\vec{E}|$$

μ_+ : ion mobility

for ions $v_D \sim E/P$, i.e. for constant pressure constant mobility

typical:

$E \sim 1 \text{ kV / cm-atm}$

μ_- : electron mobility

in cold gas approximation ($T_{\text{kin}} \sim kT$) $\rightarrow v_D \sim E$, $\mu = \text{const.}$

in hot gas ($T_{\text{kin}} \gg kT$) $\rightarrow v_D = \text{const.}$, $\mu = \text{not const.}$

Compare:

Electrons: v_D of order cm/ μs

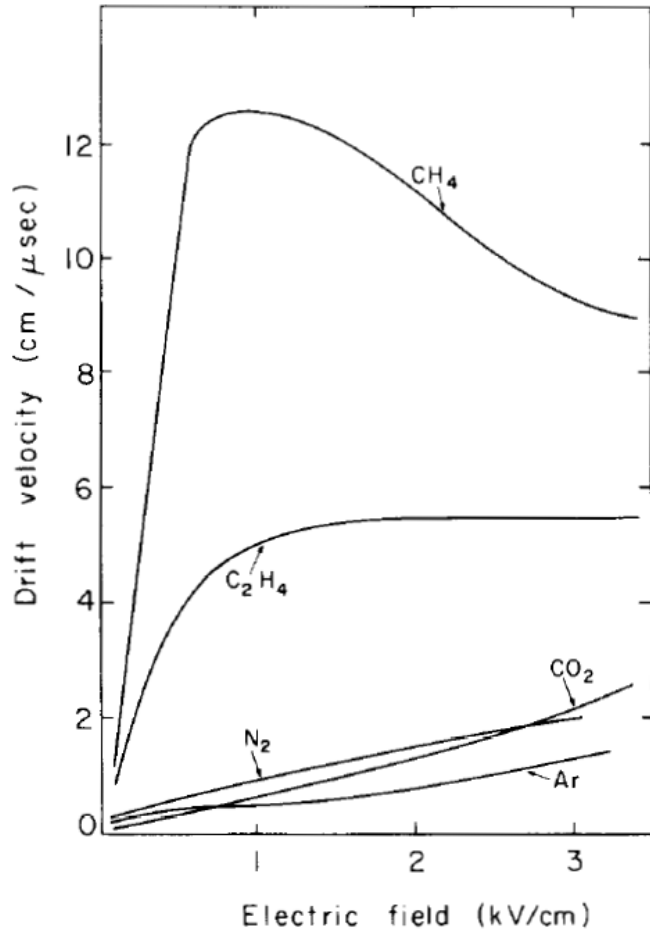
Ions: v_D of order cm/ms

$$D/\mu = kT/e$$

Einstein relation for ideal gases in thermal equilibrium

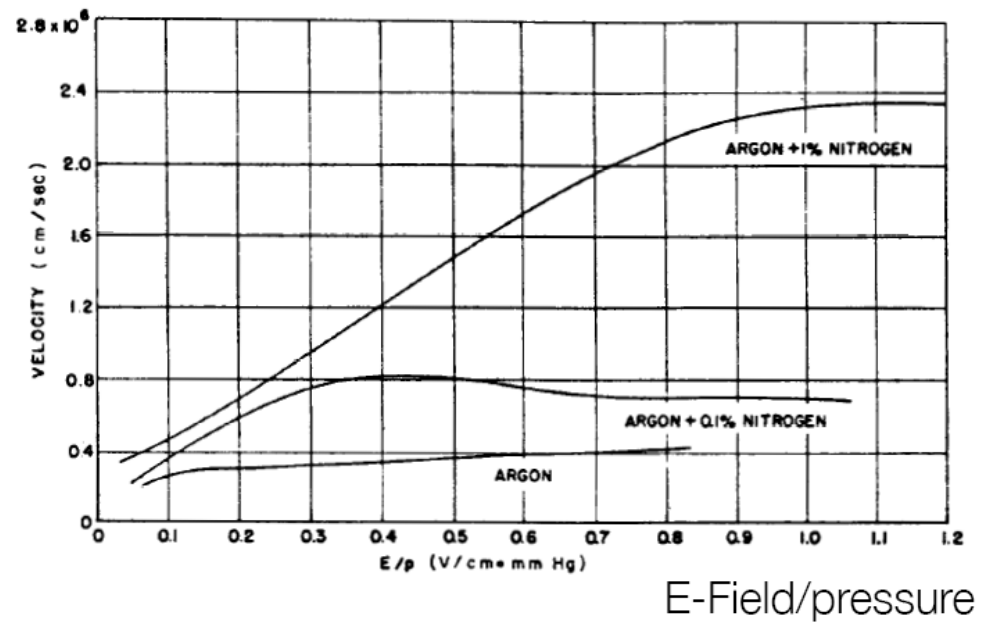
the gain in velocity may affect the diffusion rate and thereby the time behavior of the detector (e.g. drift chamber)

Drift velocity

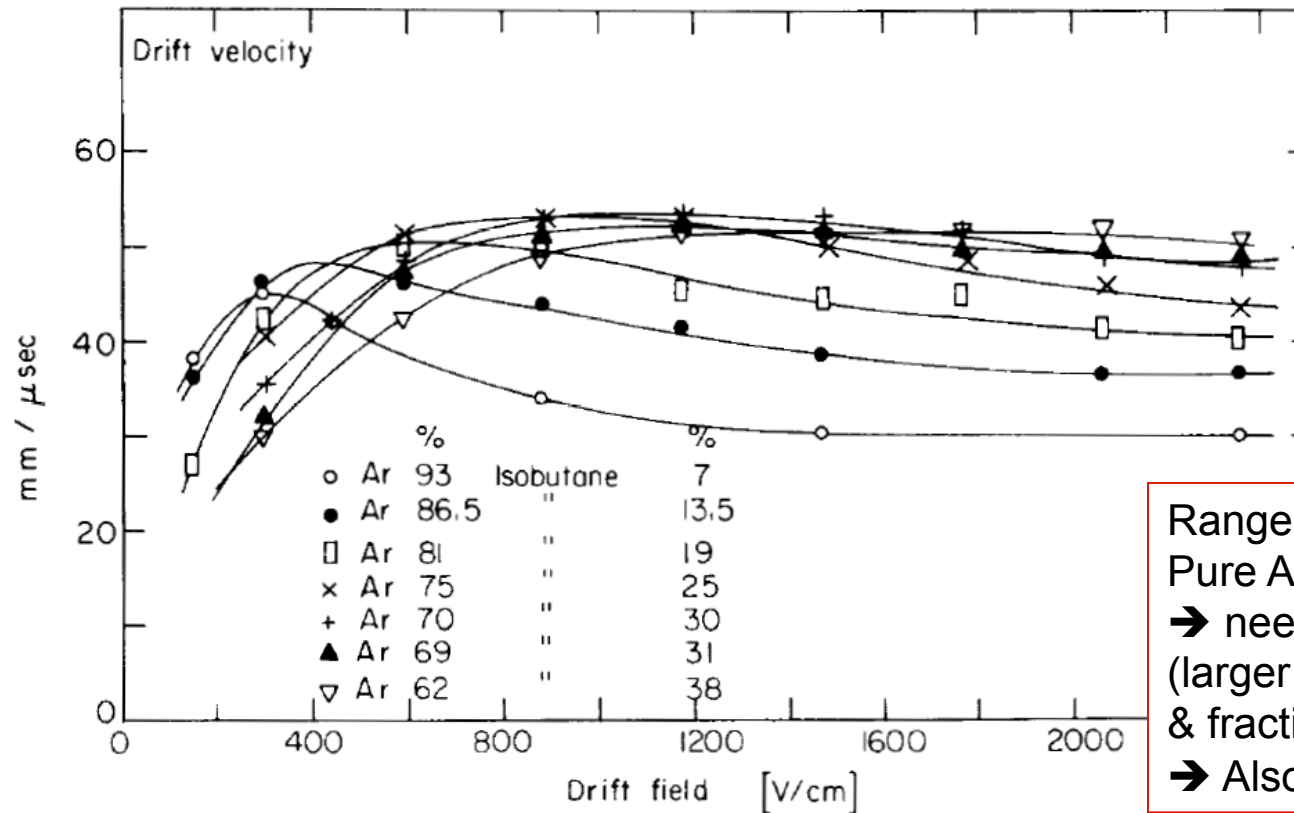


Drift velocity of electrons
in several gases at normal conditions

Use gas mixture to obtain constant v_D
Important for applications using drift time to get
spatial information



Drift velocity



Range: few 10 mm/ μs
Pure Ar : ~ 10 mm/ μs
→ need quenching gas
(larger cross-sections
& fractional energy loss)
→ Also less diffusion

Drift velocity in several argon-isobutane (C_4H_{10}) mixtures

Avalanche multiplication

Large electric field yields
large kinetic energy of electrons ...

→ Avalanche formation

Larger mobility of electrons results in liquid
drop like avalanche with electrons near head ...

Mean free path: λ_{ion}
[for a secondary ionization]

Probability of an ionization per
unit path length: $\alpha = 1/\lambda_{\text{ion}}$ [1st Townsend coefficient]

$$dn = n \cdot \alpha dx$$

$$n = n_0 e^{\alpha x}$$

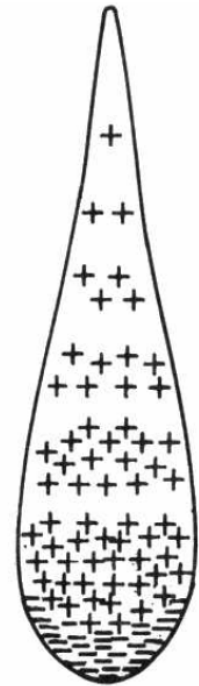
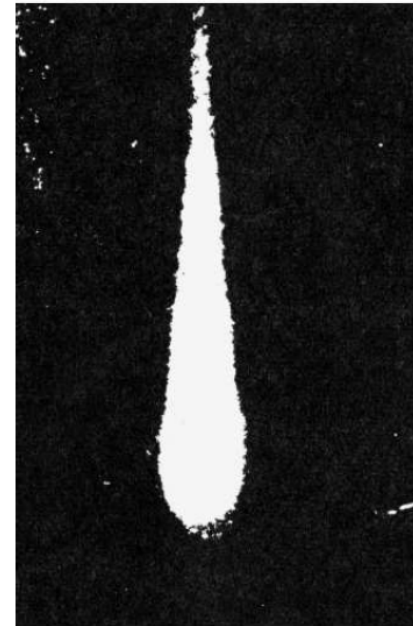
$n(x) =$ electrons
at location x

Gain:

$$G = \frac{n}{n_0} = e^{\alpha x} \quad \text{and more general for } \alpha = \alpha(x): \quad G = \frac{n}{n_0} = \exp \left[\int_{x_1}^{x_2} \alpha(x) dx \right]$$

[Raether limit: $G \approx 10^8$; $\alpha x = 20$; then sparking sets in ...]

Townsend avalanche



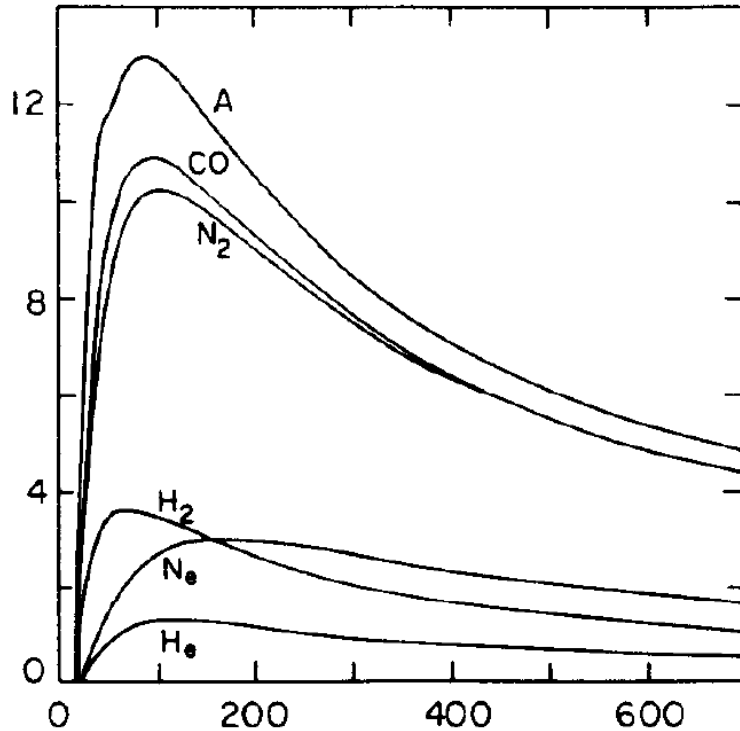
Drop-like shape of an avalanche

Left: cloud chamber picture

Right: schematic view

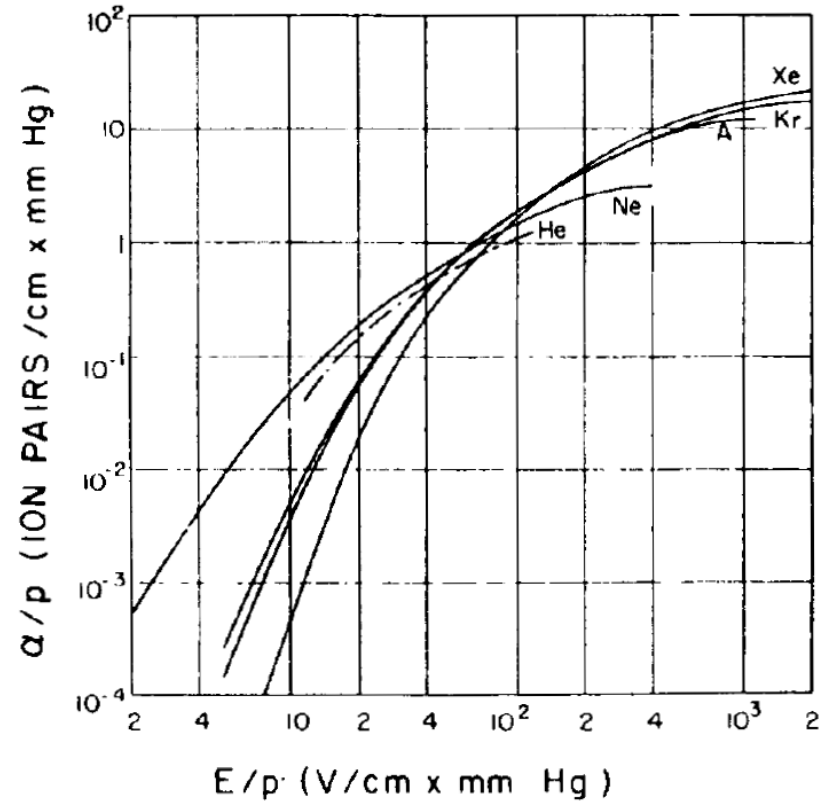
Avalanche multiplication

Ionization Probability



Need about 75-100 eV
for high ionization probability
[need to gain this energy within few microns]

Townsend Coefficient



$E \approx 75$ kV/cm
needed to reach $\alpha = 1$

Gas amplification factor

Ionization mode:

full charge collection
no multiplication; gain ≈ 1

Proportional mode:

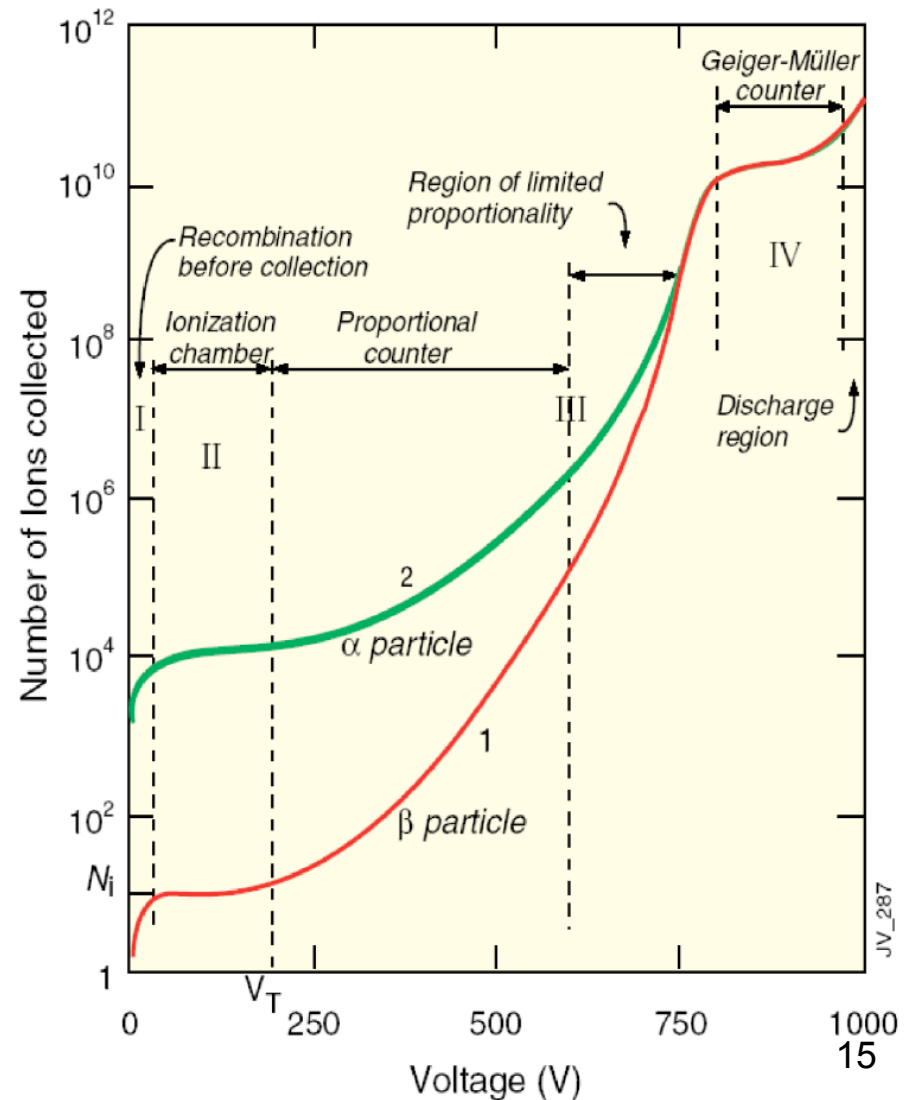
multiplication of ionization
signal proportional to ionization
measurement of dE/dx
secondary avalanches need quenching;
gain $\approx 10^4 - 10^5$

Limited proportional mode: [saturated, streamer]

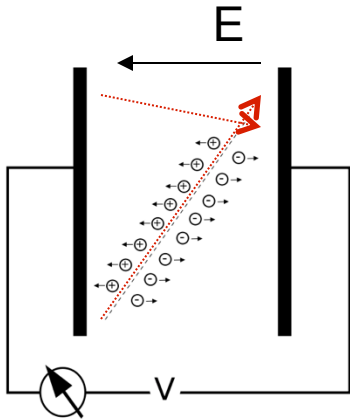
strong photoemission
requires strong quenchers or pulsed HV;
gain $\approx 10^{10}$

Geiger mode:

massive photoemission;
full length of the anode wire affected;
discharge stopped by HV cut



Proportional counter

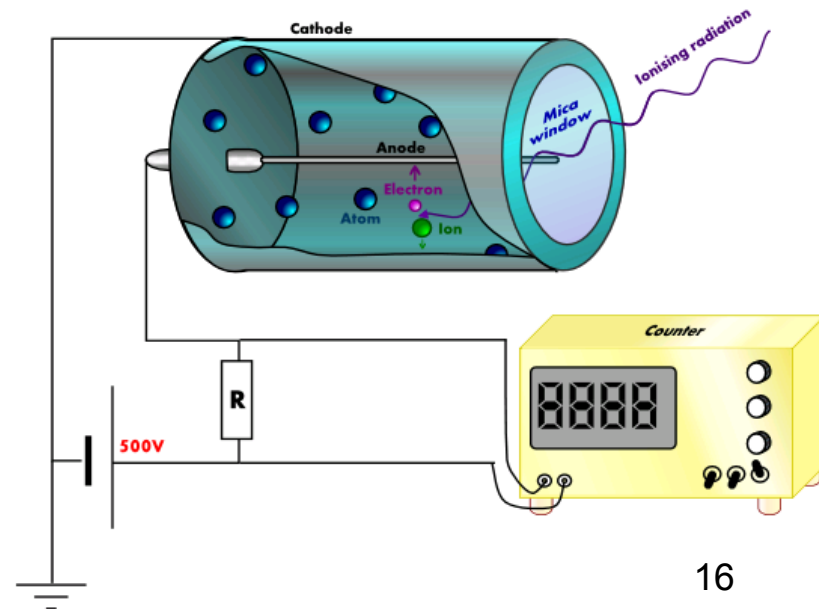


Planar design disadvantage:

E uniform and \perp to the electrodes
amount of ionization produced proportional to path length
and to position where the ionization occurs
→ not proportional to energy

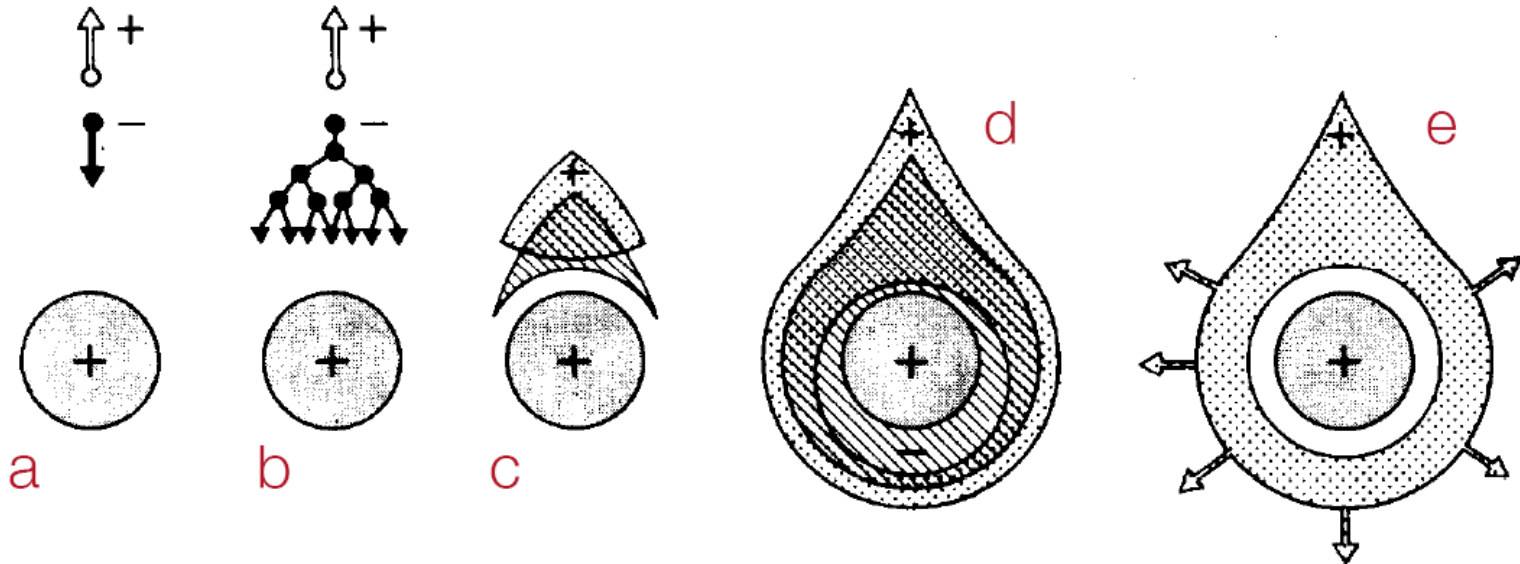
Problem solved using **Cylindrical proportional counter:**

Single anode wire in a cylindrical cathode
 $E \sim 1/r$: weak field far from the wire
electrons/ions drift in the volume
multiplication occurs only near the anode



Avalanche development

Time development of an avalanche near the wire of a proportional counter

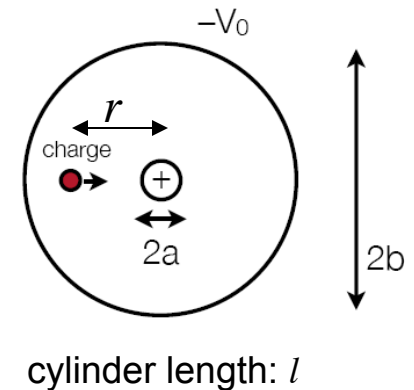


- a) a single primary electron proceeds towards the wire anode,
- b) in the region of increasingly high field the electron experiences ionizing collisions (avalanche multiplication),
- c) electrons and ions are subject to lateral diffusion,
- d) a drop-like avalanche develops which surrounds the anode wire,
- e) the electrons are quickly collected ($\sim 1\text{ns}$) while the ions begin drifting towards the cathode generating the signal at the electrodes.

Signal pulse formation and shape

Pulse formation and shape:

Again, pulse signal is formed by induction due to the movement of charges towards cathode and anode ...



Electric field:

$$E(r) = \frac{CV_0}{2\pi\epsilon_0} \frac{1}{r} \quad \text{with } C = \frac{2\pi\epsilon_0}{\ln b/a}$$

Electric potential:

$$\phi(r) = -\frac{CV_0}{2\pi\epsilon_0} \ln \frac{r}{a}$$

[Capacity per unit length]

Consider charge q :

[Assume fast charge movement ...]

No compensation
by power supply

$$dW = q \frac{d\phi(r)}{dr} dr \quad \text{change in potential energy}$$

$$dW = l CV_0 dV \quad \text{electrostatic energy}$$

→

$$q \frac{d\phi(r)}{dr} dr = l CV_0 dV$$

$$dV = \frac{q}{l CV_0} \frac{d\phi(r)}{dr} dr$$

from: $W = 1/2 l CV_0^2$

[Capacity: lC !]

Integrate ...

Energy conservation (closed system)

Signal pulse formation and shape

Integrate ...

$$dV = \frac{q}{lCV_0} \frac{d\phi(r)}{dr} dr \quad \text{with} \quad \phi(r) = -\frac{CV_0}{2\pi\epsilon_0} \ln \frac{r}{a}$$

Total induced voltage
for electrons:

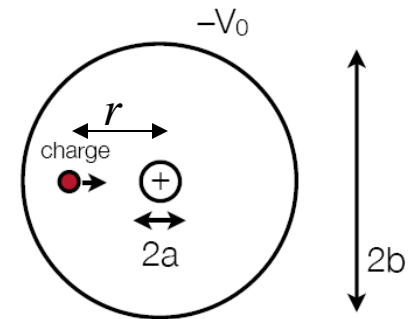
$$V^- = -\frac{q}{lCV_0} \int_{a+r'}^a \frac{d\phi(r)}{dr} dr = -\frac{q}{lCV_0} \left[\frac{CV_0}{2\pi\epsilon_0} \ln \left(\frac{a+r'}{a} \right) \right]$$

r' : point where the multiplication starts

$$= -\frac{q}{2\pi\epsilon_0 l} \ln \left(\frac{a+r'}{a} \right)$$

Total induced voltage
for ions:

$$V^+ = \frac{q}{lCV_0} \int_{a+r'}^b \frac{d\phi(r)}{dr} dr = -\frac{q}{2\pi\epsilon_0 l} \ln \left(\frac{b}{a+r'} \right)$$



cylinder length: l

Cross check:

$$V = V^+ + V^- = -\frac{q}{lC} \quad \text{with} \quad C = \frac{2\pi\epsilon_0}{\ln b/a}$$

Ratio of V^+ and V^- :

$$\left. \frac{V^-}{V^+} = \frac{\ln(a+r'/a)}{\ln(b/a+r')} \right]$$

With typical numerical values:
 $a = 10 \mu\text{m}$, $b = 10 \text{mm}$, $r' = 1 \mu\text{m}$
 $V^-/V^+ = 0.013$

Signal almost entirely
due to ions ...

Signal pulse formation and shape

Ignoring electron signal
and setting $r(0) = a \dots$

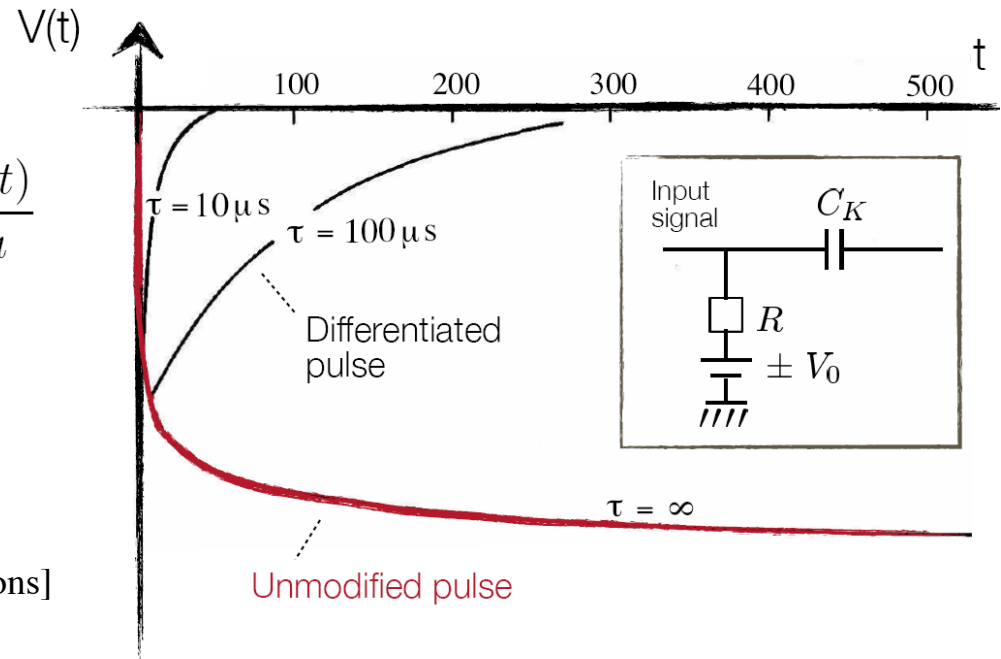
$$V(t) = \int_{r(0)}^{r(t)} \frac{dV}{dr} dr = -\frac{q}{2\pi\epsilon_0 l} \ln \frac{r(t)}{a}$$

Calculation of $r(t)$:

$$v_D = \frac{dr}{dt} = \mu E(r) = \frac{\mu C V_0}{2\pi\epsilon_0} \frac{1}{r}$$

$$r dr = \frac{\mu C V_0}{2\pi\epsilon_0} dt \quad [r(0)=a \text{ for ions}]$$

$$\rightarrow r(t) = \left(a^2 + \frac{\mu C V_0}{\pi\epsilon_0} t \right)^{1/2}$$



Differentiator:
Measure output voltage across resistor ...

Voltage time dependence:

$$V(t) = -\frac{q}{4\pi\epsilon_0 l} \ln \left(1 + \frac{\mu C V_0}{\pi\epsilon_0 a^2} t \right) = -\frac{q}{4\pi\epsilon_0 l} \ln \left(1 + \frac{t}{t_0} \right)$$

with:

$$t_0 = \pi\epsilon_0 a^2 / \mu C V_0$$

Signal pulse formation and shape

Total drift time T:

with:

$$t_0 = \pi \epsilon_0 a^2 / \mu C V_0$$

$$\left. \begin{aligned} r(T) &= b \\ b &= \left(a^2 + \frac{\mu C V_0 T}{\pi \epsilon_0} \right)^{1/2} \end{aligned} \right] T = \frac{\pi \epsilon_0}{\mu C V_0} (b^2 - a^2) = t_0 \left(\frac{b^2}{a^2} - 1 \right)$$

Calculation $V(a/b \cdot T)$:

$$\begin{aligned} V(a/b \cdot T) &= -\frac{q}{4\pi \epsilon_0 l} \ln \left(1 + \frac{a/b \cdot T}{t_0} \right) = -\frac{q}{4\pi \epsilon_0 l} \ln \left(1 + a/b \left(\frac{b^2}{a^2} - 1 \right) \right) \\ &= -\frac{q}{4\pi \epsilon_0 l} \ln \left(\frac{b}{a} \right) = -\frac{1}{2} \frac{q}{lC} \end{aligned}$$

$$\text{with } C = \frac{2\pi \epsilon_0}{\ln b/a}$$

[Capacity per unit length]

Typically $a/b \approx 10^{-3}$, i.e. after $10^{-3} T$ already half of the signal voltage is reached ...

Choice of suitable RC-circuit allows short (differentiated) signals ...

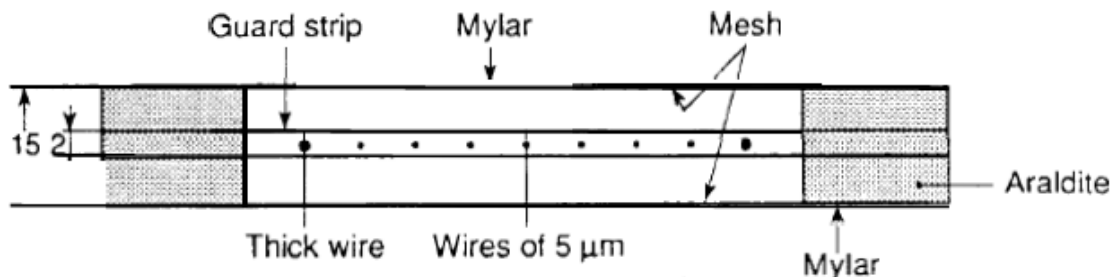
Brief recap

So far:

- we have defined the ionization and avalanche multiplication process
- we have the design of a single wire proportional counter
- with it we can measure the pulse signal from ionization

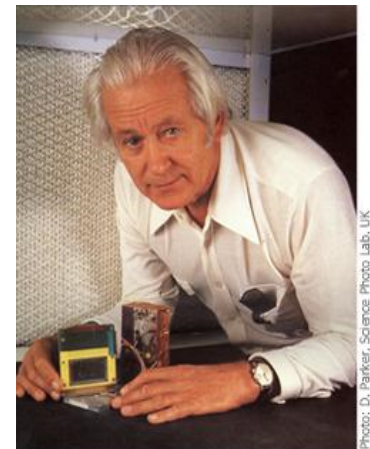
A proportional counter does not yet give a position measurement of the incident particle ...

multi-wire proportional chamber



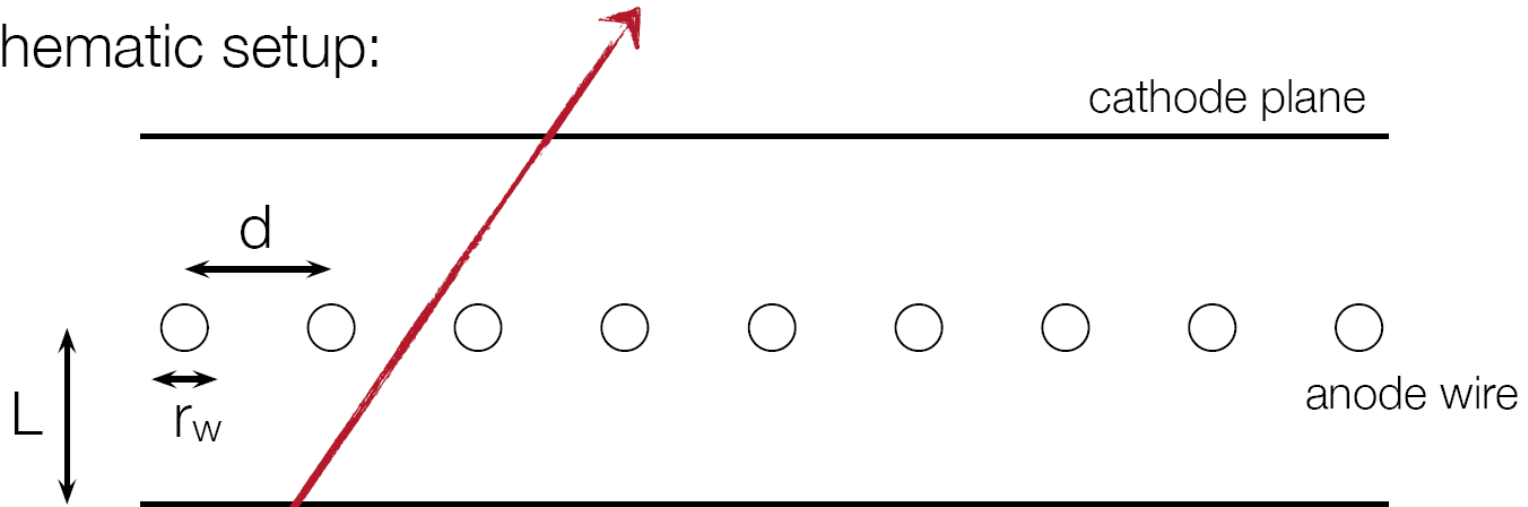
construction details of the original design of Charpak's multi-wire chambers

G. Charpak
Nobel price (1992)



Multi-wire proportional chamber (MWPC)

Schematic setup:



Parameters:

- $d = 2 - 4 \text{ mm}$
- $r_w = 20 - 25 \text{ } \mu\text{m}$
- $L = 3 - 6 \text{ mm}$
- $U_0 = \text{several kV}$
- Total area: $O(\text{m}^2)$

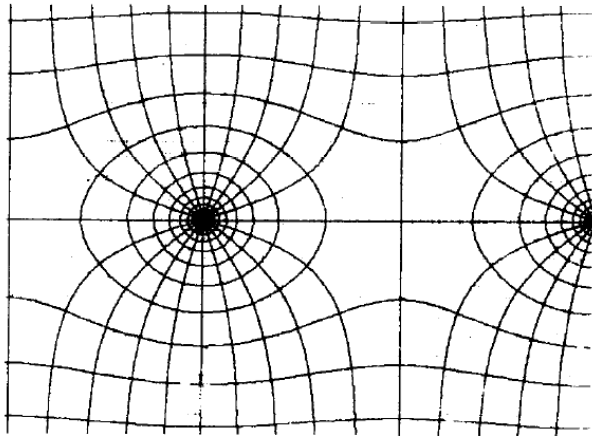
Features:

- Tracking of charged particles
- Some PID capabilities via dE/dx
- Large area coverage
- High rate capabilities

particle track

MWPC – field distribution

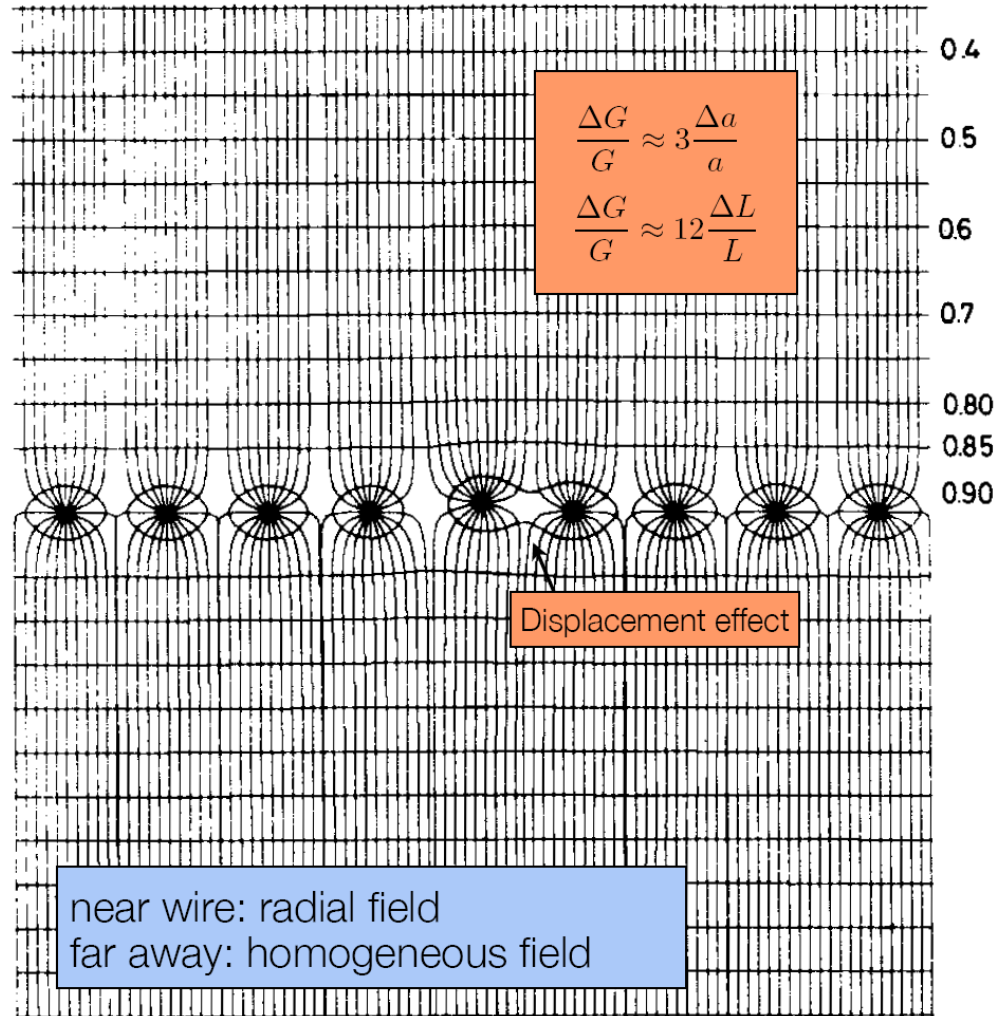
Electric field lines
and equipotentials



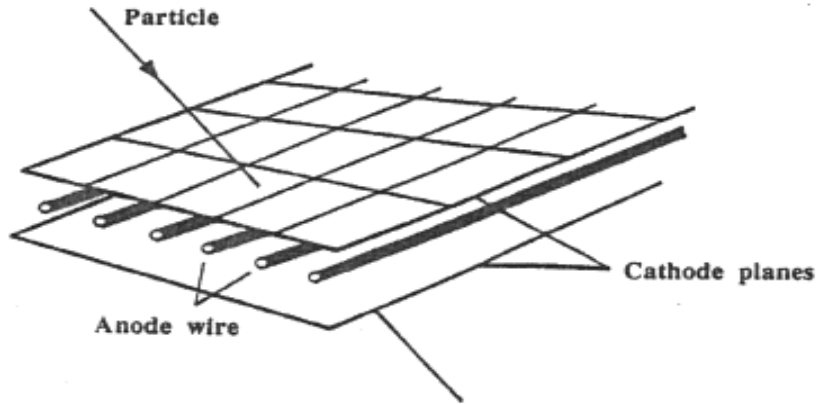
Small wire displacements
reduce field quality ...

Need high mechanical precision
both for geometry and wire tension ...

[electrostatics and gravitation; wire sag]



MWPC – signal



Signal generation:

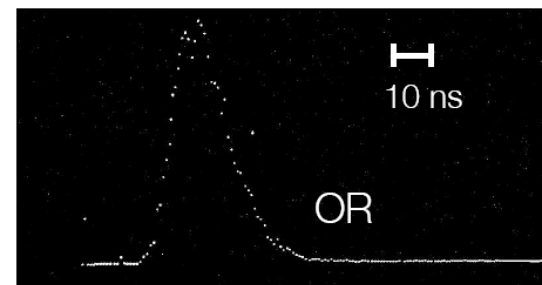
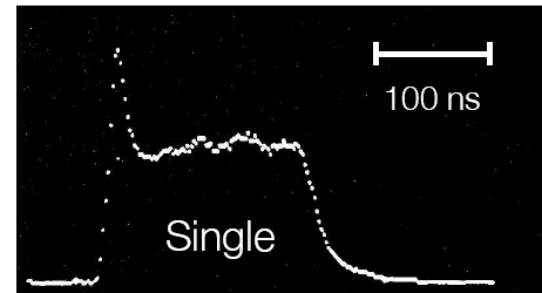
Electrons drift to closest wire

Gas amplification near wire → avalanche

Signal generation due to electrons and
mainly slow ions

Timing resolution:

Depends on location of penetration
for fast response: OR of all channels ...
[typical: $\sigma_t = 10$ ns]



Multi-wire proportional chamber

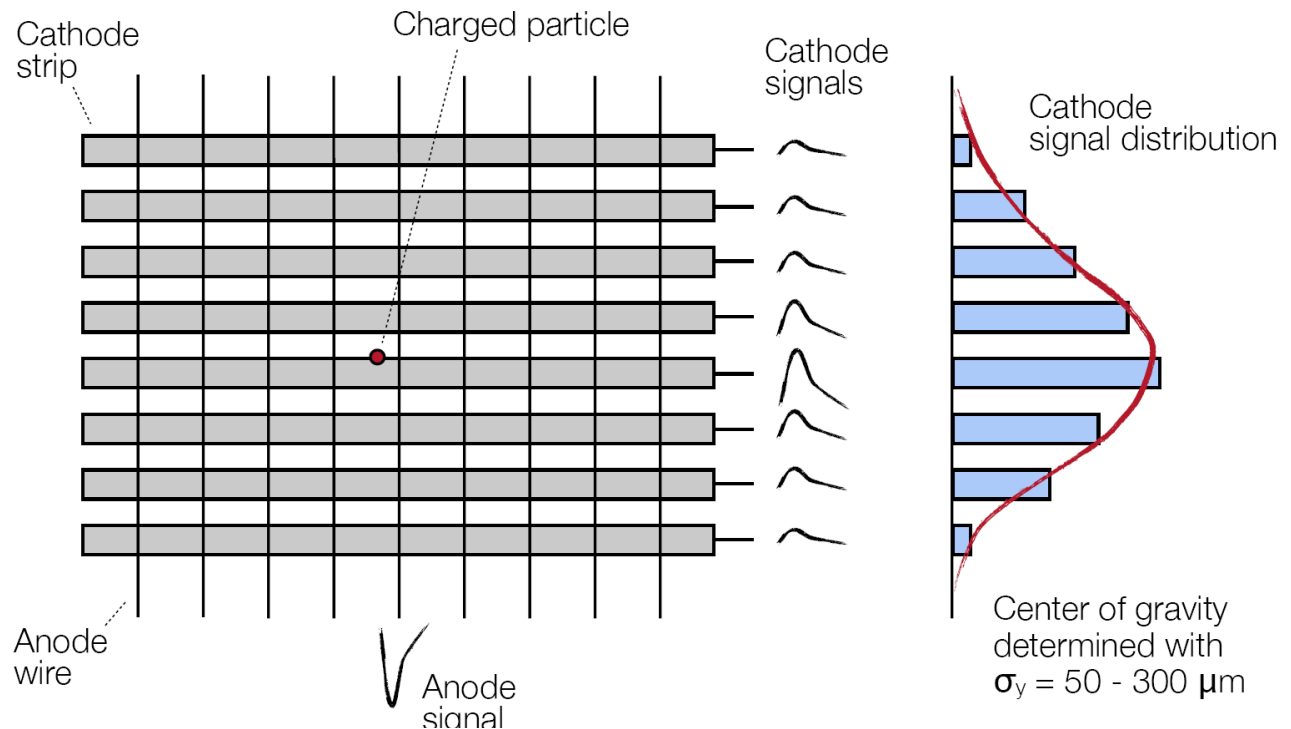
Space point resolution:

Only information about closest wire $\rightarrow \sigma_x = d/\sqrt{12}$ [d=2-4 mm, $\sigma_x \sim 0.6-1\text{mm}$]

[Only one dimension information]

Possible improvements:

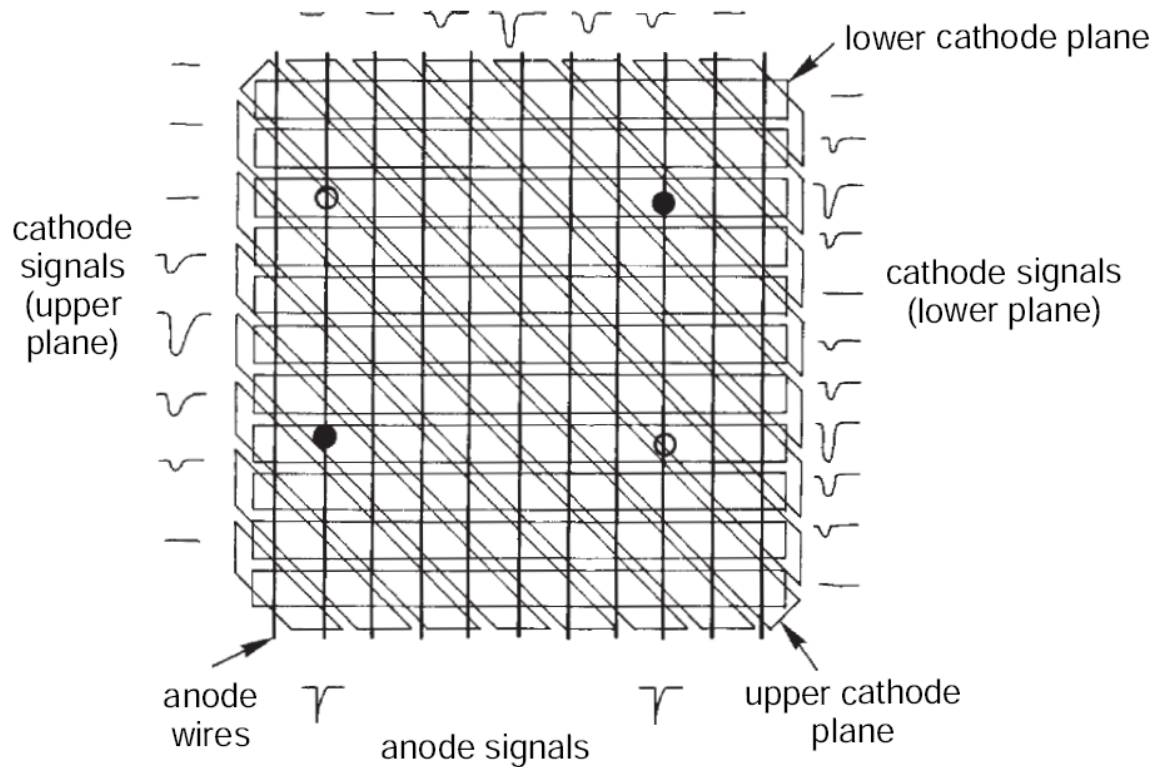
- segmented cathode



- 2-dim.: use 2 MWPCs with different orientation
- 3-dim.: several layers of such X-Y-MWPC combinations [tracking]

2D - MWPC

substantial functionality improvement
due to cathode strips/pads ...



- true hit
- ghost hit

Cathode readout
yields:

2-dim. information
true 2d: use pads ...

high spatial resolution
due to center of gravity reconstruction

resolving ambiguities
using second strip pattern or pads

Can wires be avoided?

Aging in wire chambers

Avalanche formation can be considered as micro plasma discharge.

Consequences:

- Formation of radicals i.e. molecule fragments
- Polymerisation yields long chains of molecules
- Polymers may be attached to the electrodes
- Reduction of gas amplification

Important:

Avoid unnecessary contamination ...

Harmful are ...

Halogens or halogen compounds

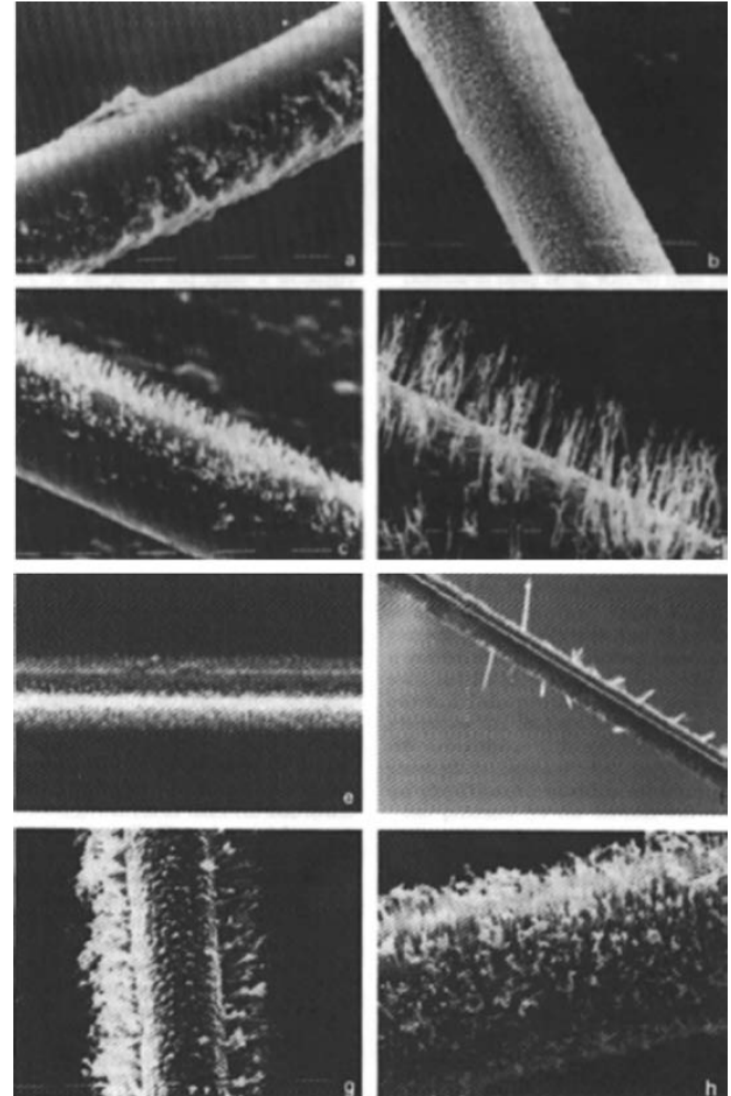
Silicon compounds

Carbonates, halocarbons

Polymers

Oil, fat ...

....



Can wires be avoided?

Micro-strip gas chambers (MSGC)

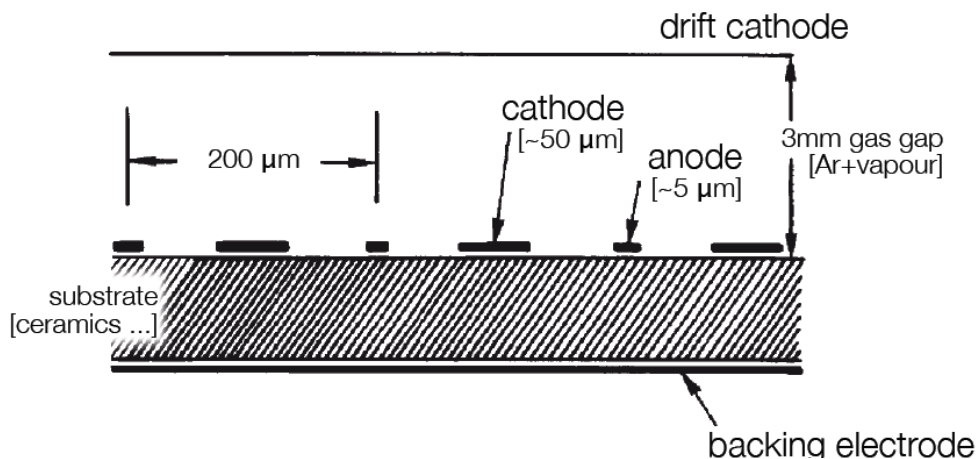
Can one avoid wires?

Anode realized via microstructures on dielectrics ...

Simple construction (today)
Enhanced stability & flexibility
Improved rate capabilities

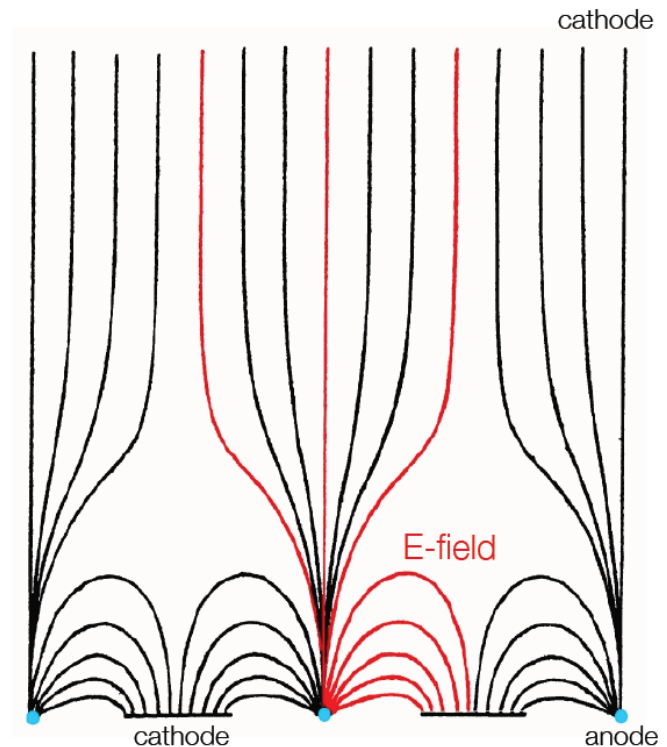
First MSGCs developed in 1990ies ...

Problems: charging of isolation structure
[-> time-dependent gain; sparks, anode destruction]



Schematics of MSGC field lines

high field directly above anode
ions drift only 100 micrometers; yields low dead time ...



MGSC – technical solutions

MGSCs prone to aging problems ...
 Solution: intermediate grid ...

e.g.: Micromegas
 GEM detectors [Sauli, 1997]

Micromegas:

Fine cathode mesh collects ions
 still fast; no wires ...

GEM (Gas Electron Multiplier):

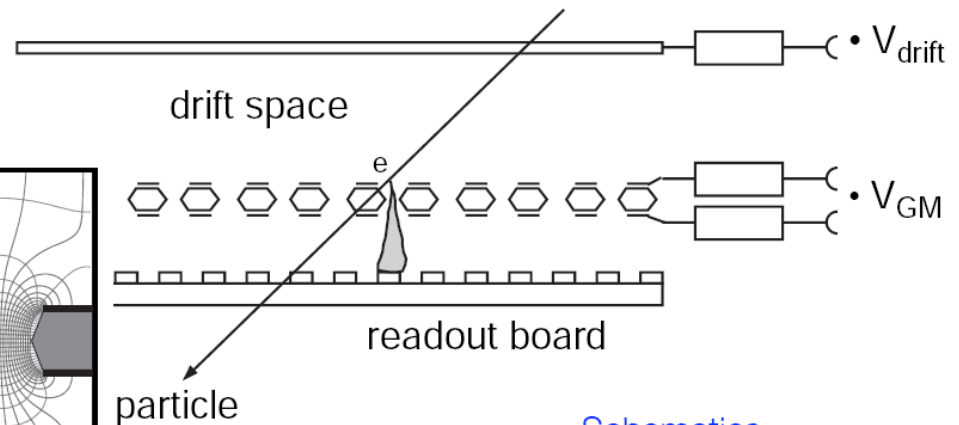
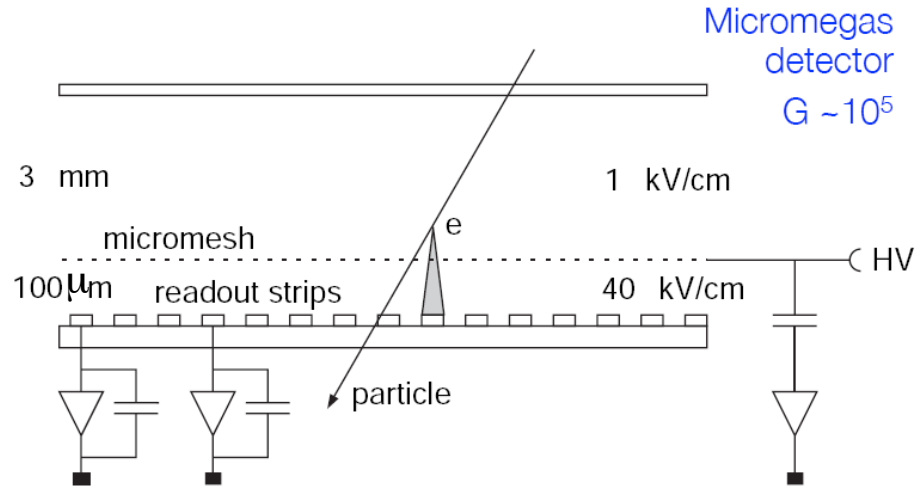
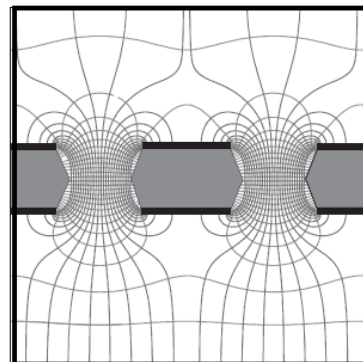
Thin insulating kapton foil
 coated with metal film ...

Contains chemically produced
 holes [100-200 μm]

Electrons are guided by high
 electric drift field of GEMs ...

Avalanche production ...

Electrons drift to anode
 GEM collects ions

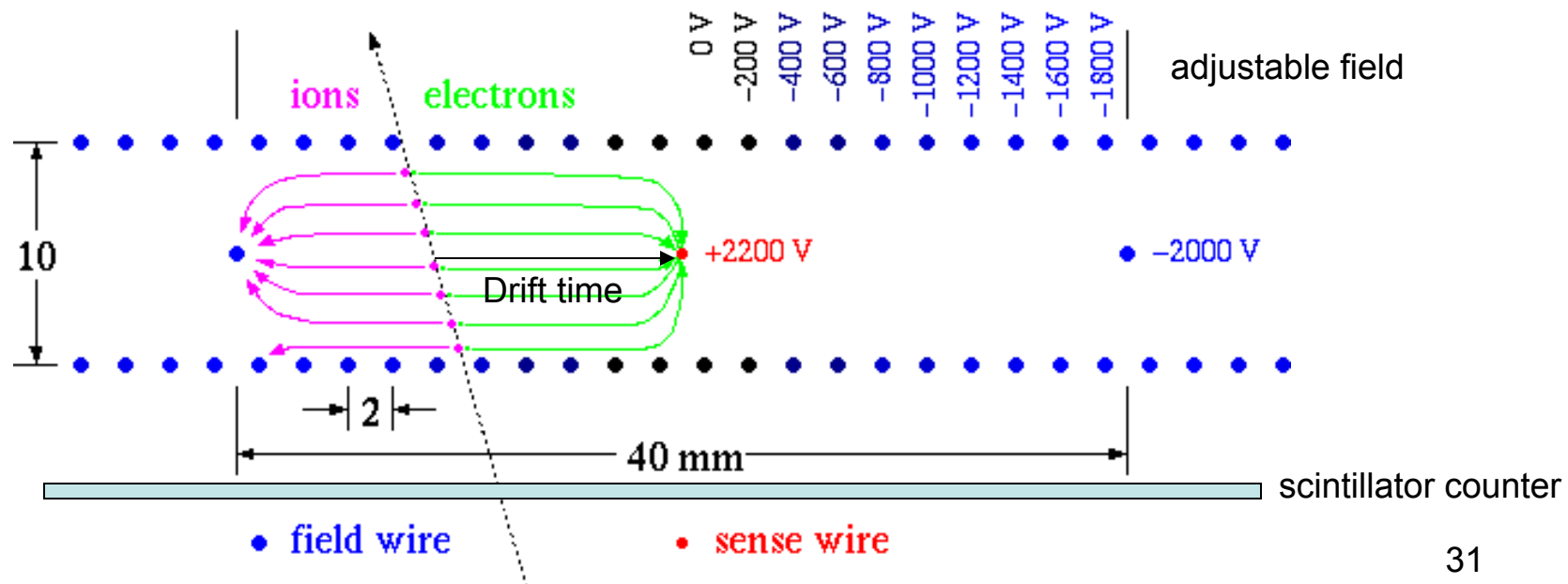


Drift chamber

Alternative way to obtain spatial information: **measure the electrons drift time**

- time measurement started by an external (fast) detector, i.e. scintillator counter
- electrons drift to the anode (sense wire), in the field created by the cathodes
- the electron arrival at the anode stops the time measurement

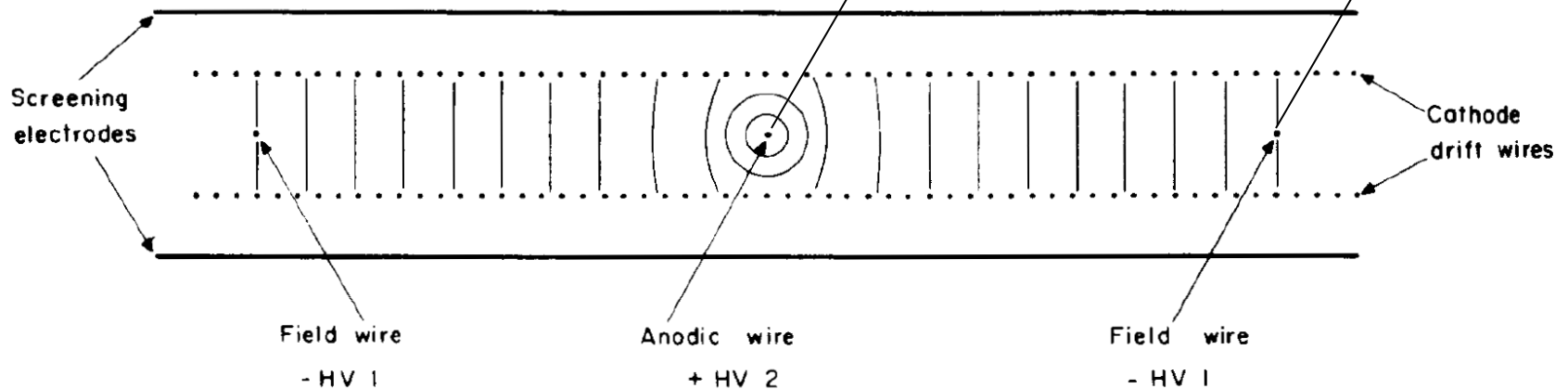
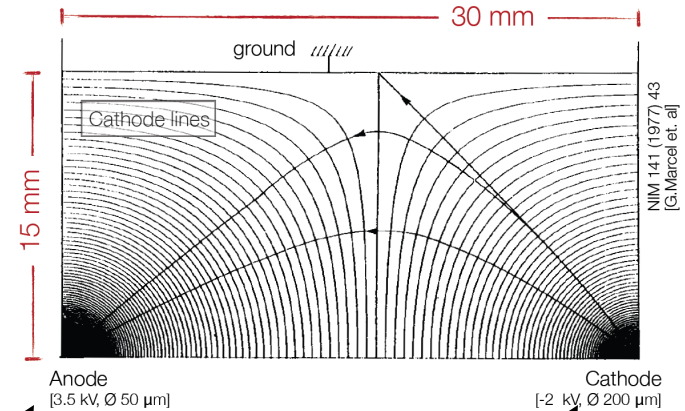
- one-coordinate measurement: $x = \int_0^{t_D} v_D dt$



Drift chamber – field formation

Introduce field wires to avoid low field regions, i.e. long drift-times

Uniform drift field requires:
Gap length/wire spacing ≈ 1
i.e. for typical convenient wire spacing one needs thick chambers $O(\text{cm})$

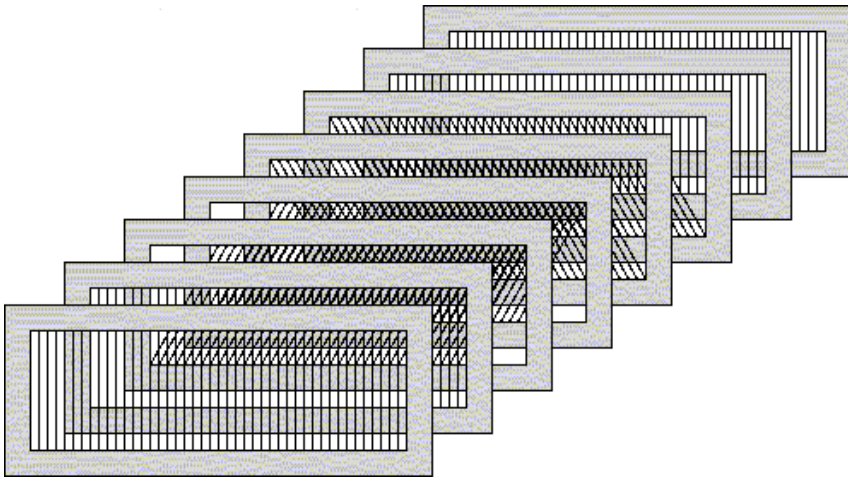


Adjustable field multi-wire drift chamber:
introduction of voltage divider
via cathode wire planes

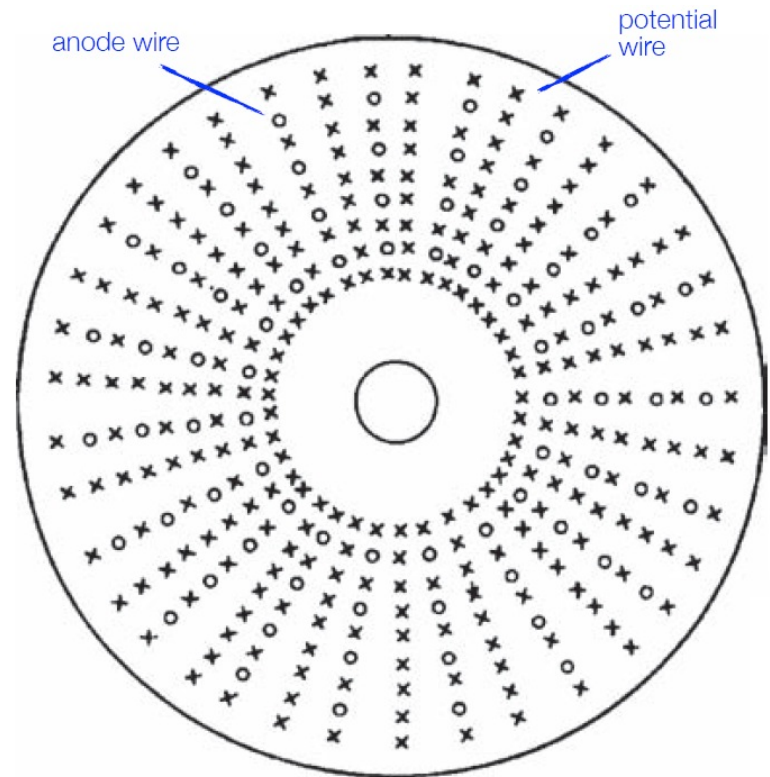
very few (or only one) anode wires
space point resolution limited by mechanical accuracy
[for large chambers: $\sigma \approx 200 \mu\text{m}$]
But: hit density needs to be low.

Tracking detector

Tracking at fixed target experiments:
Multi-layer MWPC or drift chamber

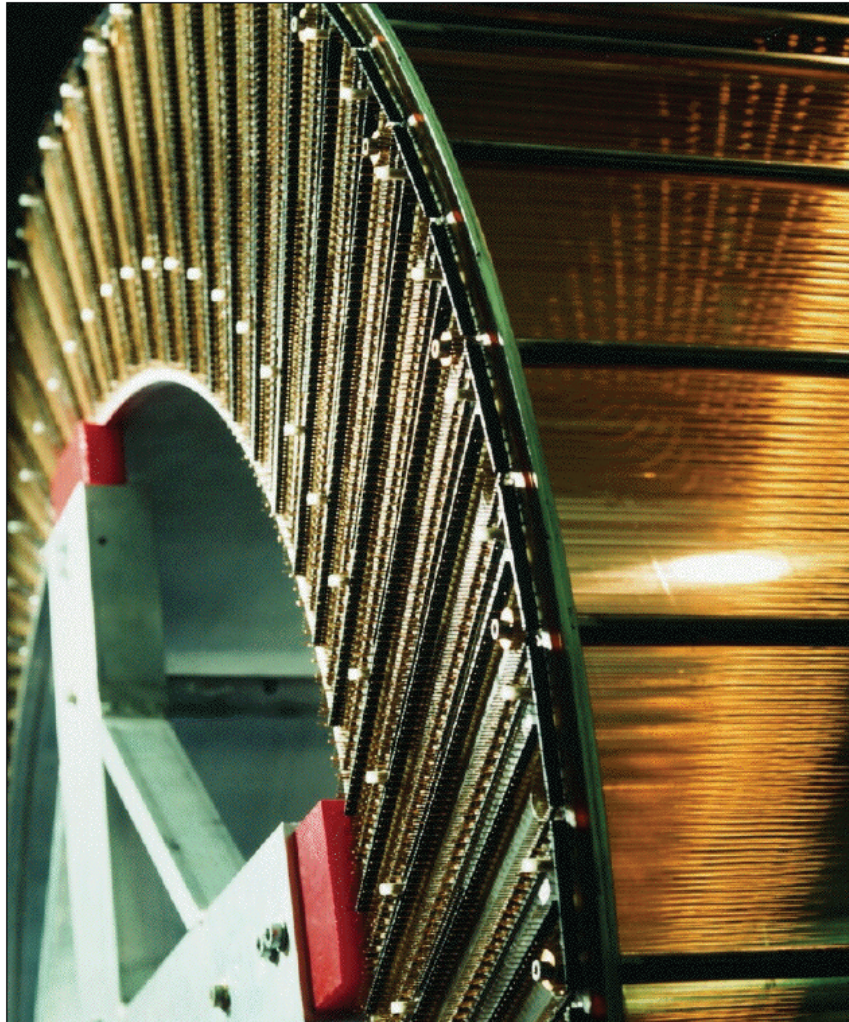


Tracking at collider experiments:
cylindrical drift chamber



... more about tracking in the next lecture

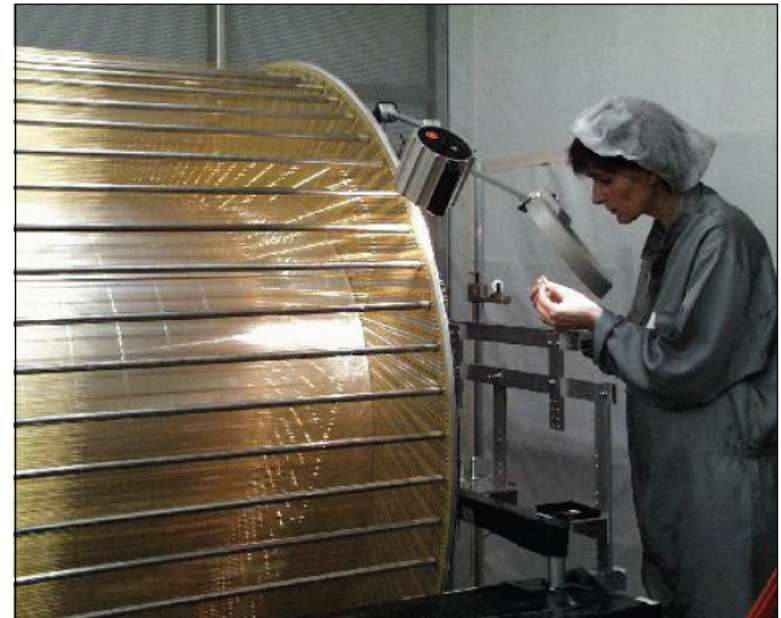
H1 - Cylindrical drift chamber



Cylindrical
Drift Chamber

[H1 Experiment]

Number of wires: ~ 15000
Total force from wire tension: ~ 6 t



Time projection chamber

Electronic 'bubble chamber'
Full 3D reconstruction ...

xy : from wires and pads of MWPC
z : from drift time measurement

Momentum measurement ...
space point measurement
plus B field ...

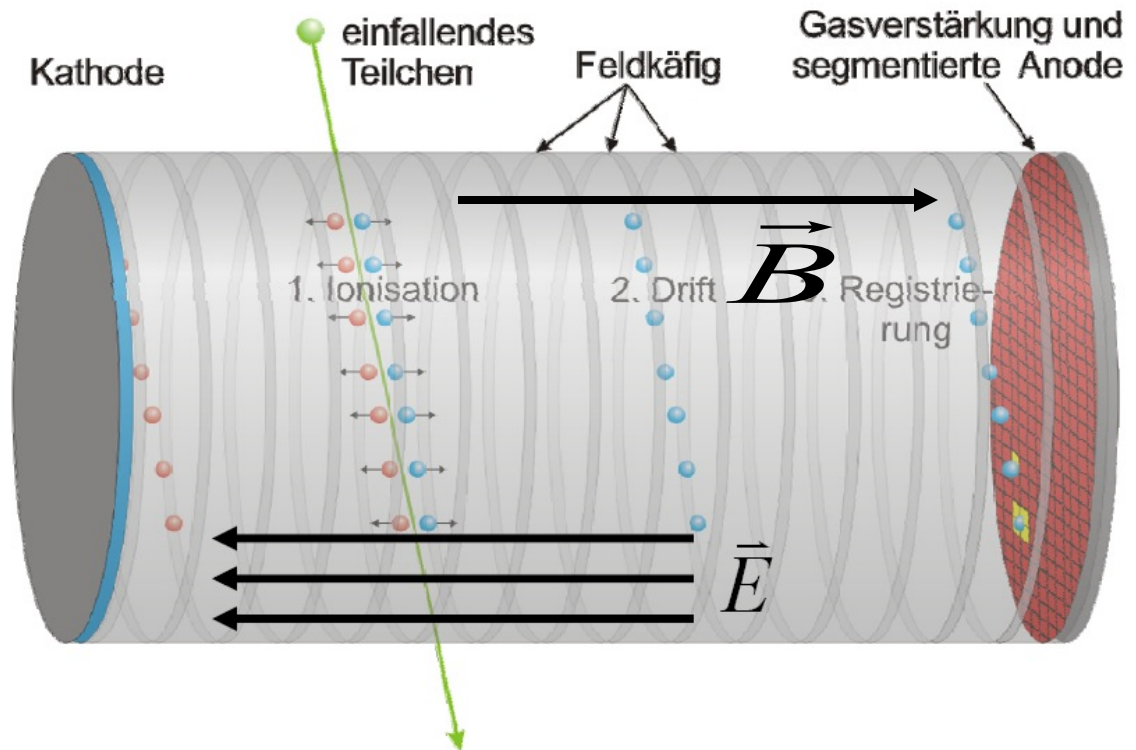
Energy measurement ...
via dE/dx ...

TPC setup:

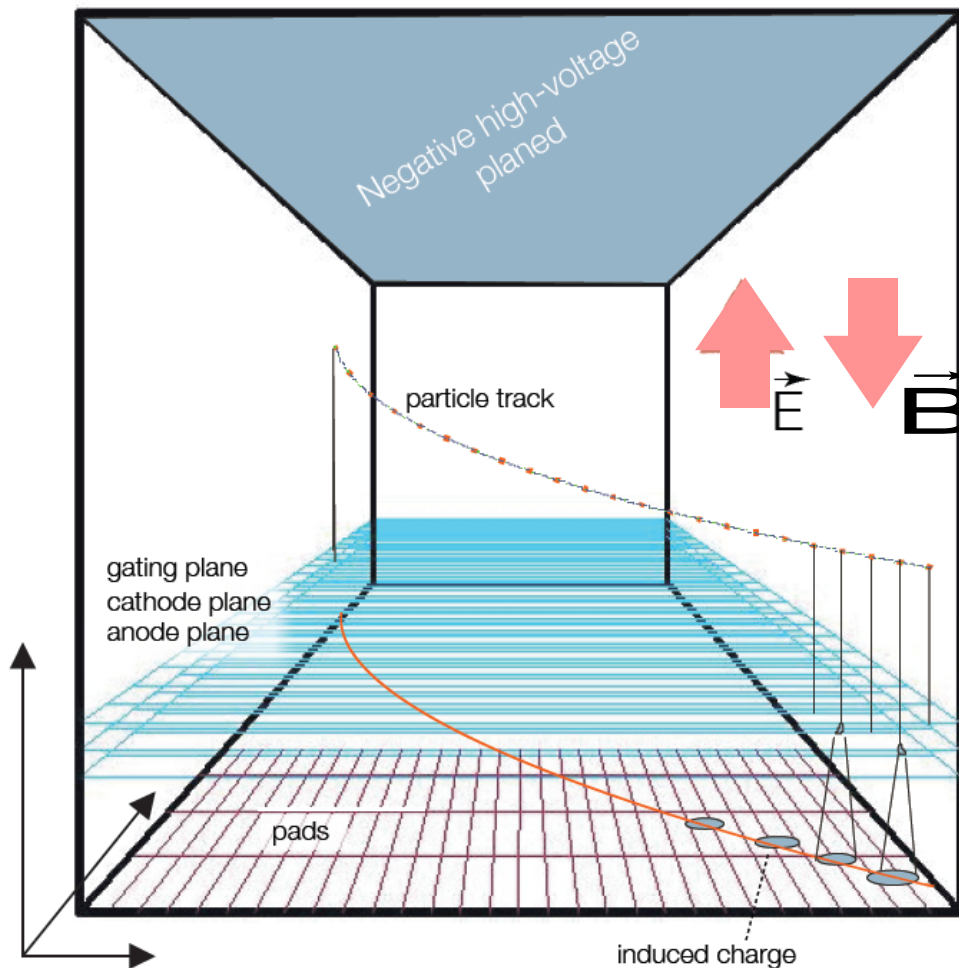
(mostly) cylindrical detector
central HV cathode
MWPCs at end-caps of cylinder
 $B \parallel$ to $E \rightarrow$ Lorentz angle = 0

Charge transport :

Electrons drift to end-caps
Drift distance several meters
Continuous sampling of induced
charges in MWPC



Time projection chamber



Advantages:

Complete track within one detector yields good momentum resolution

Relative few, short wires (MWPC only)

Good particle ID via dE/dx

Drift parallel to B suppresses transverse diffusion by factors 10 to 100

Challenges:

Long drift time; limited rate capability [attachment, diffusion ...]

Large volume [precision]

Large voltages [discharges]

Large data volume ...

Extreme load at high luminosity; gating grid opened for triggered events only ...

Typical resolution:

z : mm; x : 150 - 300 μm ; y : mm
 dE/dx : 5 - 10%

TPC – technical solution

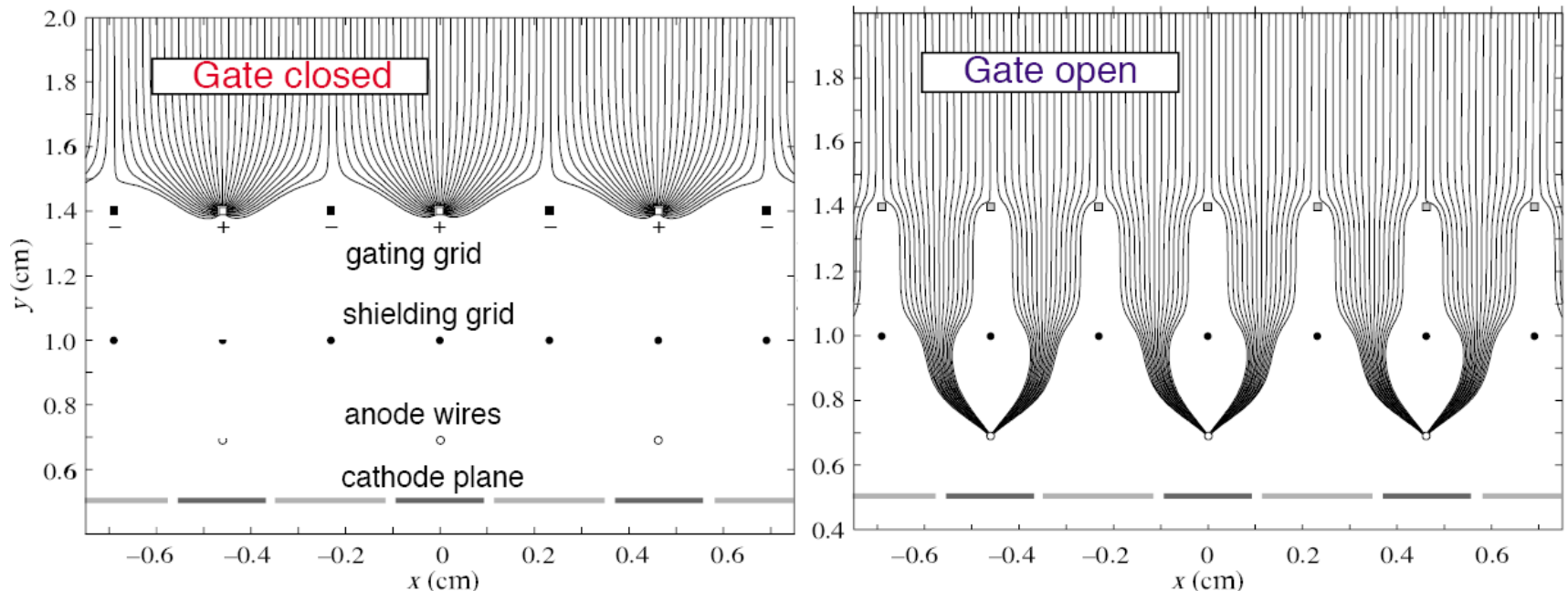
Difficulty: space charge effects due to slow moving ions
change effective E-field in drift region

Important: most ions come from amplification region

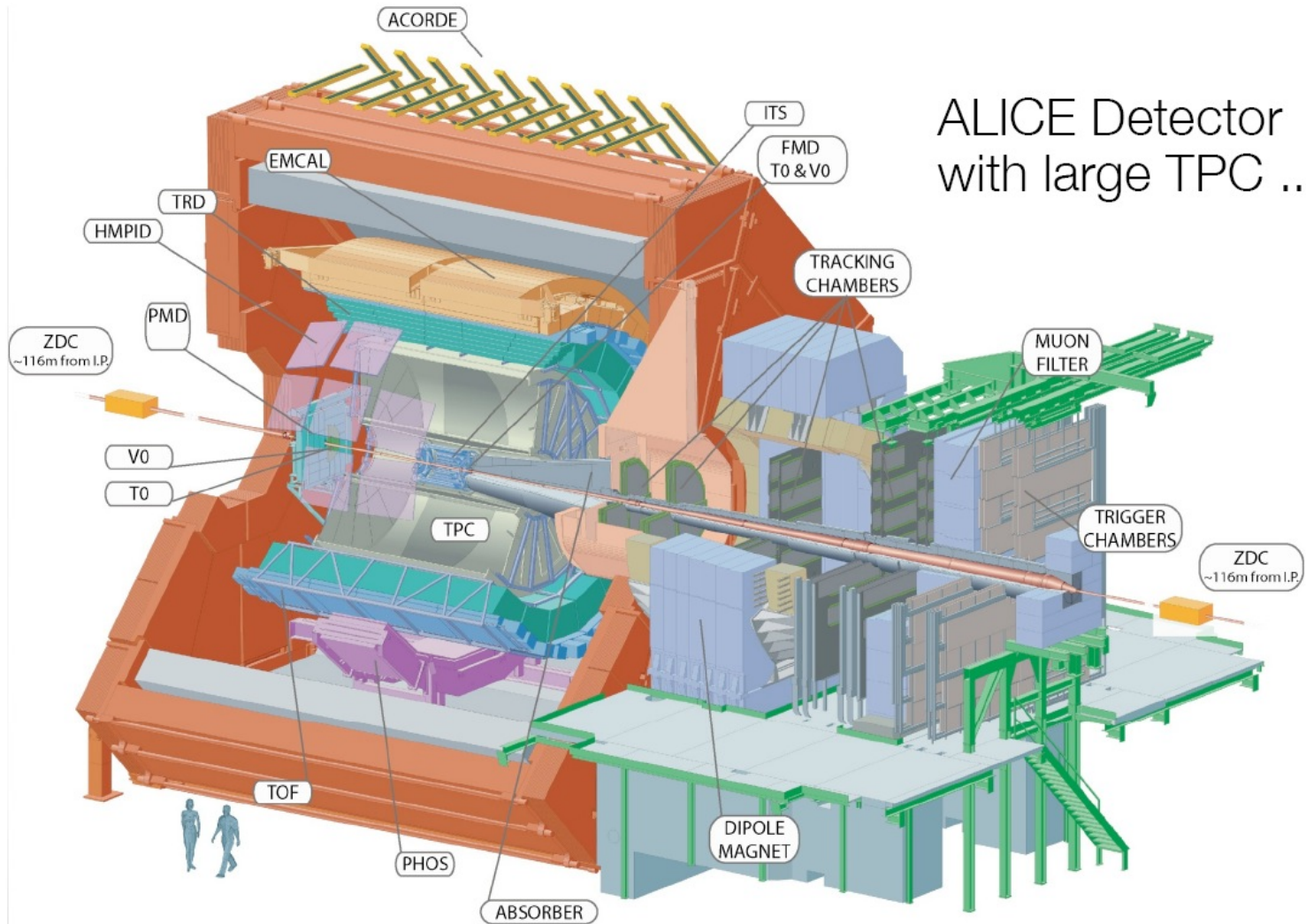
Solution: Invention of gating grid; ions drift towards grid ...

[Also: shielding grid to avoid sense wire disturbance when switching]

Requires external trigger to switch gating grid ...



ALICE - TPC



ALICE Detector
with large TPC ...

ALICE - TPC

Length: 5 meter
Radius: 2.5 meter
Gas volume: 88 m³

Total drift time: 92 μ s
High voltage: 100 kV

End-caps detectors: 32 m²
Readout pads: 557568
159 samples radially
1000 samples in time

Gas: Ne/CO₂/N₂ (90-10-5)
Low diffusion (cold gas)

Gain: > 10⁴

Diffusion: $\sigma_t = 250 \mu\text{m}$
Resolution: $\sigma \approx 0.2 \text{ mm}$

$\sigma_p/p \sim 1\% p$; $\epsilon \sim 97\%$
 $\sigma_{dE/dx}/(dE/dx) \sim 6\%$

Magnetic field: 0.5 T

Pad size: 5x7.5 mm² (inner)
6x15 mm² (outer)

Temperature control: 0.1 K
[also resistors ...]

